

TLE214x, TLE214xA
EXCALIBUR LOW-NOISE HIGH-SPEED
PRECISION OPERATIONAL AMPLIFIERS

SLOS183D – FEBRUARY 1997 – REVISED OCTOBER 2012

- **Low Noise**
10 Hz . . . 15 nV/ $\sqrt{\text{Hz}}$
1 kHz . . . 10.5 nV/ $\sqrt{\text{Hz}}$
- **10000-pF Load Capability**
- **20-mA Min Short-Circuit Output Current**
- **27-V/ μs Min Slew Rate**
- **High Gain-Bandwidth Product . . . 5.9 MHz**
- **Low V_{IO} . . . 500 μV Max at 25°C**
- **Single or Split Supply . . . 4 V to 44 V**
- **Fast Settling Time**
340 ns to 0.1%
400 ns to 0.01%
- **Saturation Recovery . . . 150 ns**
- **Large Output Swing**
 $V_{\text{CC-}} + 0.1 \text{ V}$ to $V_{\text{CC+}} - 1 \text{ V}$

description

The TLE214x and TLE214xA devices are high-performance, internally compensated operational amplifiers built using Texas Instruments complementary bipolar Excalibur process. The TLE214xA is a tighter offset voltage grade of the TLE214x. Both are pin-compatible upgrades to standard industry products.

The design incorporates an input stage that simultaneously achieves low audio-band noise of 10.5 nV/ $\sqrt{\text{Hz}}$ with a 10-Hz 1/f corner and symmetrical 40-V/ μs slew rate typically with loads up to 800 pF. The resulting low distortion and high power bandwidth are important in high-fidelity audio applications. A fast settling time of 340 ns to 0.1% of a 10-V step with a 2-k Ω /100-pF load is useful in fast actuator/positioning drivers. Under similar test conditions, settling time to 0.01% is 400 ns.

The devices are stable with capacitive loads up to 10 nF, although the 6-MHz bandwidth decreases to 1.8 MHz at this high loading level. As such, the TLE214x and TLE214xA are useful for low-droop sample-and-holds and direct buffering of long cables, including 4-mA to 20-mA current loops.

The special design also exhibits an improved insensitivity to inherent integrated circuit component mismatches as is evidenced by a 500- μV maximum offset voltage and 1.7- $\mu\text{V}/^{\circ}\text{C}$ typical drift. Minimum common-mode rejection ratio and supply-voltage rejection ratio are 85 dB and 90 dB, respectively.

Device performance is relatively independent of supply voltage over the $\pm 2\text{-V}$ to $\pm 22\text{-V}$ range. Inputs can operate between $V_{\text{CC-}} - 0.3$ to $V_{\text{CC+}} - 1.8 \text{ V}$ without inducing phase reversal, although excessive input current may flow out of each input exceeding the lower common-mode input range. The all-npn output stage provides a nearly rail-to-rail output swing of $V_{\text{CC-}} - 0.1$ to $V_{\text{CC+}} - 1 \text{ V}$ under light current-loading conditions. The device can sustain shorts to either supply since output current is internally limited, but care must be taken to ensure that maximum package power dissipation is not exceeded.

Both versions can also be used as comparators. Differential inputs of $V_{\text{CC}\pm}$ can be maintained without damage to the device. Open-loop propagation delay with TTL supply levels is typically 200 ns. This gives a good indication as to output stage saturation recovery when the device is driven beyond the limits of recommended output swing.

Both the TLE214x and TLE214xA are available in a wide variety of packages, including both the industry-standard 8-pin small-outline version and chip form for high-density system applications. The C-suffix devices are characterized for operation from 0°C to 70°C, I-suffix devices from -40°C to 105°C, and M-suffix devices over the full military temperature range of -55°C to 125°C.



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 **TEXAS
INSTRUMENTS**

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TLE2141 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES		
		SMALL OUT- LINE† (D)	CERAMIC DIP (JG)	PLASTIC DIP (P)
0°C to 70°C	500 µV 900 µV	TLE2141ACD TLE2141CD	—	TLE2141ACP TLE2141CP
–40°C to 105°C	500 µV 900 µV	TLE2141AID TLE2141ID	—	TLE2141AIP TLE2141IP
–55°C to 125°C	500 µV 900 µV	— TLE2141MD	TLE2141AMJG TLE2141MJG	— —

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLE2141ACDR).

TLE2142 AVAILABLE OPTIONS

PACKAGED DEVICES							
T _A	V _{IO} max AT 25°C	SMALL OUTLINE† (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	TSSOP‡ (PW)	CERAMIC FLAT PACK (U)
0°C to 70°C	750 µV	TLE2142ACD	—	—	TLE2142ACP	—	—
	1200 µV	TLE2142CD	—	—	TLE2142CP	TLE2142CPWLE	—
–40°C to 105°C	750 µV	TLE2142AID	—	—	TLC2142AIP	—	—
	1200 µV	TLE2142ID	—	—	TLC2142IP	—	—
–55°C to 125°C	750 µV	TLE2142AMD	TLE2142AMFK	TLE2142AMJG	—	—	TLE2142AMU
	1200 µV	TLE2142MD	TLE2142MFK	TLE2142MJG	—	—	TLE2142MU

† The D packages are available taped and reeled. Add R suffix to device type (e.g., TLC2142ACDR).

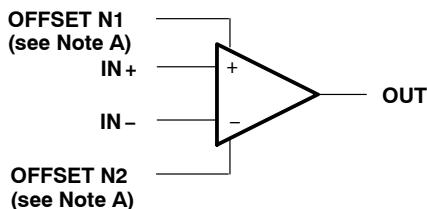
‡ The PW packages are available left-ended taped and reeled. Add LE the suffix to device type (e.g., TLC2142CPWLE).

TLE2144 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE† (DW)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)
0°C to 70°C	1.5 mV	—	—	—	TLE2144ACN
	2.4 mV	TLE2144CDW	—	—	TLE2144CN
–40°C to 105°C	1.5 mV	—	—	—	TLE2144AIN
	2.4 mV	TLE2144IDW	—	—	TLE2144IN
–55°C to 125°C	1.5 mV	—	TLE2144AMFK	TLE2144AMJ	—
	2.5 mV	TLE2144MDW	TLE2144MFK	TLE2144MJ	—

† The DW packages are available taped and reeled. Add R suffix to device type (e.g., TLE2144CDWR).

symbol

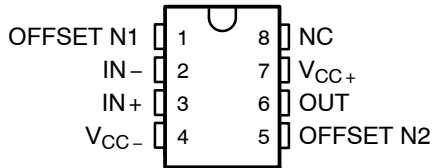


NOTES: A. OFFSET N1 AND OFFSET N2 are only available on the TLE2241x devices.

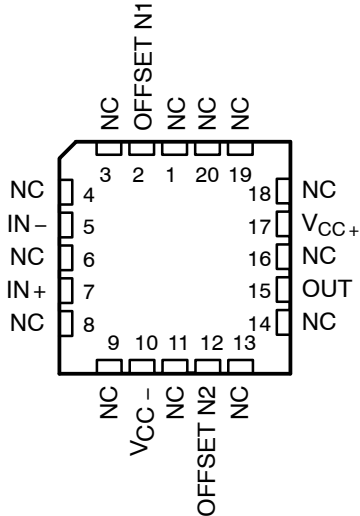
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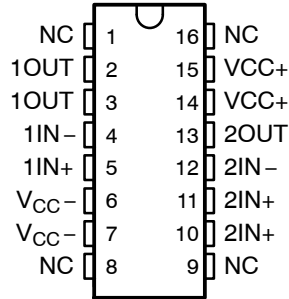
TLE2141
D, JG, OR P PACKAGE
(TOP VIEW)



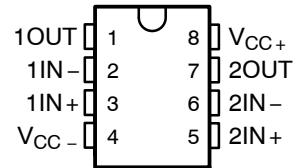
TLE2141
FK PACKAGE
(TOP VIEW)



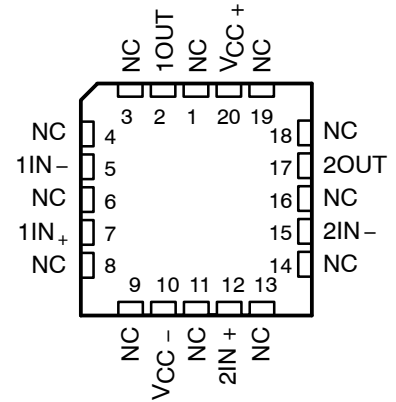
TLE2142
PW PACKAGE
(TOP VIEW)



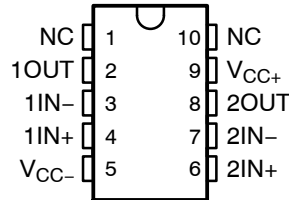
TLE2142
D, JG, OR P PACKAGE
(TOP VIEW)



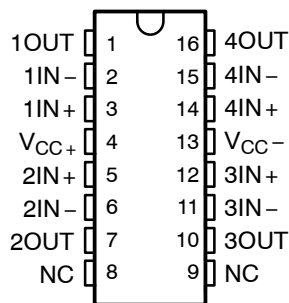
TLE2142
FK PACKAGE
(TOP VIEW)



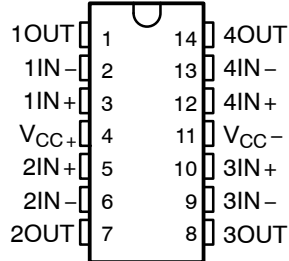
TLE2142
U PACKAGE
(TOP VIEW)



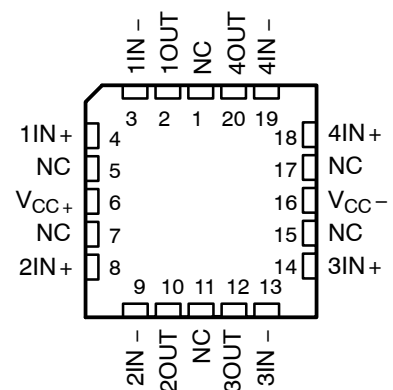
TLE2144
DW PACKAGE
(TOP VIEW)



TLE2144
J OR N PACKAGE
(TOP VIEW)

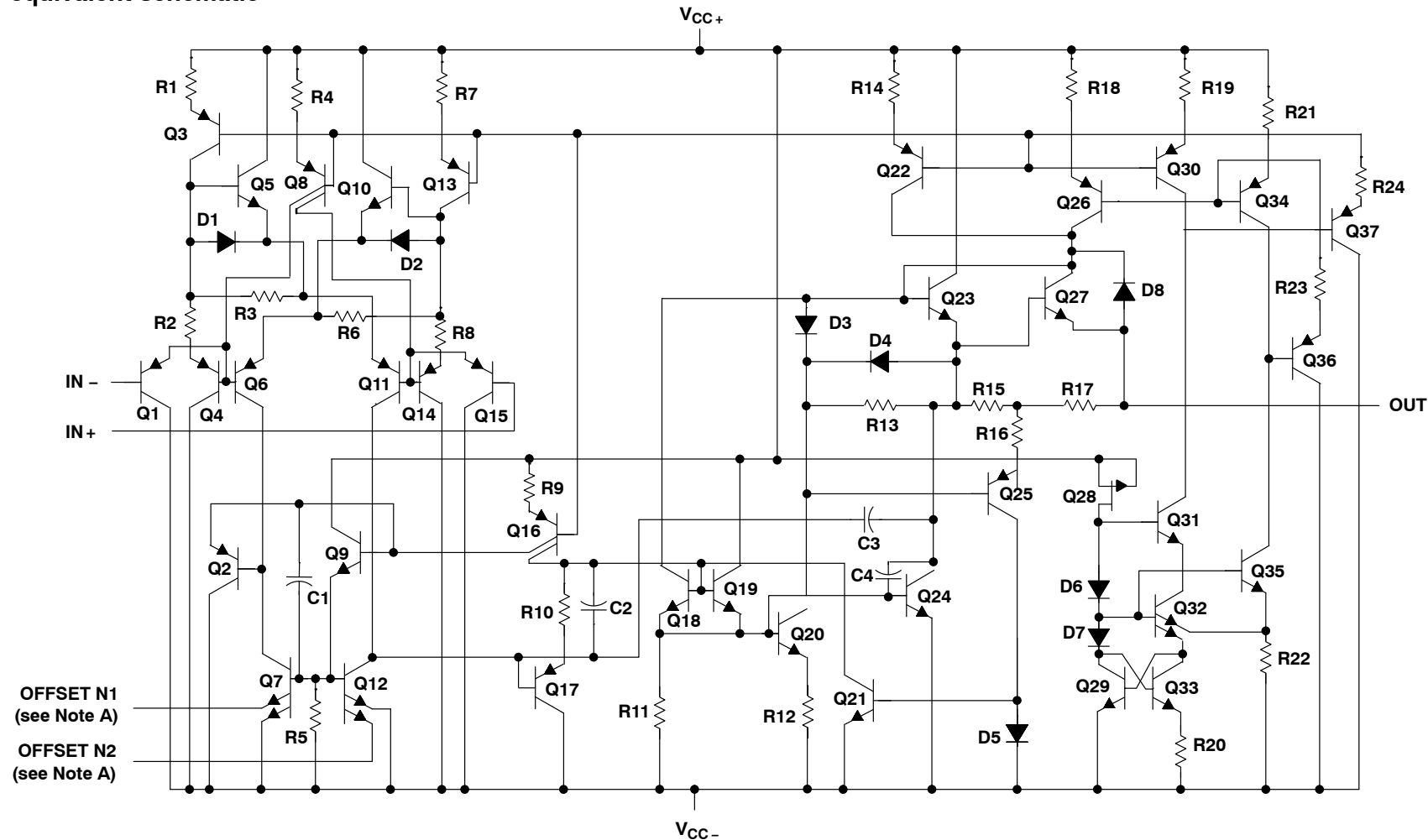


TLE2144
FK PACKAGE
(TOP VIEW)



NC – No internal connection

equivalent schematic



NOTE A: OFFSET N1 AND OFFSET N2 are only available on the TLE2141x devices.

ACTUAL DEVICE COMPONENT COUNT			
COMPONENT	TLE2141	TLE2142	TLE2144
Transistors	46	65	130
Resistors	24	43	86
Diodes	8	14	28
Capacitors	4	8	16
Epi-FET	1	1	2

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC+} (see Note 1)	22 V
Supply voltage, V_{CC-}	–22 V
Differential input voltage, V_{ID} (see Note 2)	±44 V
Input voltage range, V_I (any input)	V_{CC+} to $V_{CC-} - 0.3$ V
Input current, I_I (each input)	±1 mA
Output current, I_O	±80 mA
Total current into V_{CC+}	80 mA
Total current out of V_{CC-}	80 mA
Duration of short-circuit current at (or below) 25°C (see Note 3)	unlimited
Package thermal impedance, θ_{JA} (see Notes 4 and 5): D package	97.1°C/W
DW package	57.3°C/W
N package	79.7°C/W
P package	84.6°C/W
PW package	108.4°C/W
Package thermal impedance, θ_{JC} (see Notes 4 and 5): FK package	5.6°C/W
J package	15.1°C/W
JG package	14.5°C/W
U package	14.7°C/W
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	–40°C to 105°C
M suffix	–55°C to 125°C
Storage temperature range	–65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D, DW, N, P, or PW package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J or JG package	300°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
 2. Differential voltages are at $IN+$ with respect to $IN-$. Excessive current flows, if input, are brought below $V_{CC-} - 0.3$ V.
 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.
 4. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
 5. The package thermal impedance is calculated in accordance with JESD 51-7 (plastic) or MIL-STD-883 Method 1012 (ceramic).

recommended operating conditions

		C SUFFIX		I SUFFIX		M SUFFIX		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, $V_{CC\pm}$		±2	±22	±2	±22	±2	±22	V
Common-mode input voltage, V_{IC}	$V_{CC} = 5$ V	0	2.9	0	2.7	0	2.7	V
	$V_{CC\pm} = \pm 15$ V	–15	12.9	–15	12.7	–15	12.7	
Operating free-air temperature, T_A		0	70	–40	105	–55	125	°C

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TLE2141C electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141C			TLE2141AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$ $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	225	1400		200	1000		μV
		Full range		1700			1300		
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		150			150		
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range		–2.1			–2.1		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.9			0 to 2.9			
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
		Full range	3.8			3.8			
	$I_{OH} = -1.5\text{ mA}$	25°C	3.8	4		3.8	4		
		Full range	3.7			3.7			
	$I_{OH} = -15\text{ mA}$	25°C	3.2	3.7		3.2	3.7		
		Full range	3.2			3.2			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C		75	125		75	125	mV
		Full range			150			150	
	$I_{OL} = 1.5\text{ mA}$	25°C		150	225		150	225	
		Full range			250			250	
	$I_{OL} = 15\text{ mA}$	25°C		1.2	1.6		1.2	1.6	V
		Full range			1.7			1.7	
A_{VD} Large-signal differential voltage amplification	$V_{CC} = \pm 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_O = 1\text{ V}$ to -1.5 V	25°C	50	220		50	220		V/mV
		Full range	25			25			
r_i Input resistance		25°C		70			70		$\text{M}\Omega$
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V}$ to $\pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, No load, $V_{IC} = 2.5\text{ V}$	25°C		3.4	4.4		3.4	4.4	mA
		Full range			4.6			4.6	

[†] Full range is 0°C to 70°C.

TLE2141C operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141C			TLE2141AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}^\dagger$, $R_L = 2\text{ k}\Omega$, †		45			45			V/ μ s
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μ s
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$	10.5			10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μ V
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$	$C_L = 100\text{ pF}^\dagger$	5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}^\dagger$	5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}^\dagger$		660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$	$C_L = 100\text{ pF}^\dagger$	57°			57°			

† R_L and C_L terminated to 2.5 V.

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TLE2141C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2141C			TLE2141AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _{IC} = 0, R _S = 50 Ω, V _O = 0		25°C	200		900	175		500	μV
	Full range			1300		800					
α _{VIO}	Temperature coefficient of input offset voltage			Full range	1.7		1.7		μV/°C		
I _{IO}	Input offset current			25°C	7		100	7		100	nA
				Full range	150		150				
I _{IB}	Input bias current			25°C	−0.7		−1.5	−0.7		−1.5	μA
				Full range	−1.6		−1.6				
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω		25°C	−15 to 13	−15.3 to 13.2	−15 to 13		−15.3 to 13.2	V	
				Full range	−15 to 12.9	−15.3 to 13.1	−15 to 12.9		−15.3 to 13.1		
V _{OM+}	Maximum positive peak output voltage swing	I _O = −150 μA		25°C	13.8		14.1	13.8		14.1	V
				Full range	13.7		13.7				
				25°C	13.7		14	13.7		14	
				Full range	13.6		13.6				
				25°C	13.1		13.7	13.1		13.7	
				Full range	13		13				
V _{OM−}	Maximum negative peak output voltage swing	I _O = 150 μA		25°C	−14.7		−14.9	−14.7		−14.9	V
				Full range	−14.6		−14.6				
				25°C	−14.5		−14.8	−14.5		−14.8	
				Full range	−14.4		−14.4				
				25°C	−13.4		−13.8	−13.4		−13.8	
				Full range	−13.3		−13.3				
A _{VD}	Large-signal differential voltage amplification	V _O = ±10 V		25°C	100		450	100		450	V/mV
				Full range	75		75				
r _i	Input resistance	R _L = 2 kΩ		25°C	65		65		MΩ		
c _i	Input capacitance			25°C	2.5		2.5		pF		
z _o	Open-loop output impedance	f = 1 MHz		25°C	30		30		Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , R _S = 50 Ω		25°C	85		108	85		108	dB
				Full range	80		80				
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±2.5 V to ±15 V, R _S = 50 Ω		25°C	90		106	90		106	dB
				Full range	85		85				
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	−25		−50	−25		−50	mA
			V _{ID} = −1 V		20		31	20		31	
I _{CC}	Supply current	V _O = 0, No load		25°C	3.5		4.5	3.5		4.5	mA
				Full range	4.7		4.7				

† Full range is 0°C to 70°C.



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TLE2141C operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141C			TLE2141AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega$	27	45		27	45		V/ μs
SR–	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		0.4			0.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$	$f = 10\text{ Hz}$		15			15		nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$	$f = 1\text{ kHz}$		10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$		0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$	$C_L = 100\text{ pF}$		6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$		5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$	$C_L = 100\text{ pF}$		58°			58°		

TLE214x, TLE214xA

EXCALIBUR LOW-NOISE HIGH-SPEED

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TLE2142C electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142C			TLE2142AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 2.5\text{ V}$	25°C	220	1900		200	1500		μV
		Full range		2200			1800		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		150			150		
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range		–2.1			–2.1		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.9			0 to 2.9			
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
		Full range	3.8			3.8			
	$I_{OH} = -1.5\text{ mA}$	25°C	3.8	4		3.8	4		
		Full range	3.7			3.7			
	$I_{OH} = -15\text{ mA}$	25°C	3.4	3.7		3.4	3.7		
		Full range	3.4			3.4			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C		75	125		75	125	mV
		Full range			150			150	
	$I_{OL} = 1.5\text{ mA}$	25°C		150	225		150	225	
		Full range			250			250	
	$I_{OL} = 15\text{ mA}$	25°C		1.2	1.4		1.2	1.4	V
		Full range			1.5			1.5	
A_{VD} Large-signal differential voltage amplification	$V_{CC} = \pm 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_O = 1\text{ V to } -1.5\text{ V}$	25°C	50	220		50	220		V/mV
		Full range	25			25			
r_i Input resistance		25°C		70			70		$\text{M}\Omega$
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, No load, $V_{IC} = 2.5\text{ V}$	25°C		6.6	8.8		6.6	8.8	mA
		Full range			9.2			9.2	

† Full range is 0°C to 70°C.

TLE2142C operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142C			TLE2142AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$ $R_L = 2\text{ k}\Omega^\dagger$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$	10.5			10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	5.9			5.9			MHz	
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$	5.8			5.8			MHz	
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	660			660			kHz	
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	57°			57°				

[†] R_L terminates at 2.5 V.

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TLE2142C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142C			TLE2142AC			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, V_O = 0, R_S = 50 \Omega$	25°C	290	1200		275	750		μV
		Full range		1600			1200		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		150			150		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.6			–1.6		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.9	–15.3 to 13.1		–15 to 12.9	–15.3 to 13.1		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
		Full range	13.7			13.7			
	$I_O = -1.5$ mA	25°C	13.7	14		13.7	14		
		Full range	13.6			13.6			
	$I_O = -15$ mA	25°C	13.3	13.7		13.3	13.7		
		Full range	13.2			13.2			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
		Full range	–14.6			–14.6			
	$I_O = 1.5$ mA	25°C	–14.5	–14.8		–14.5	–14.8		
		Full range	–14.4			–14.4			
	$I_O = 15$ mA	25°C	–13.4	–13.8		–13.4	–13.8		
		Full range	–13.3			–13.3			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V	25°C	100	450		100	450		V/mV
		Full range	75			75			
r_i Input resistance	$R_L = 2$ k Ω	25°C		65			65		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1$ V		–25	–50	–25	–50	mA
			$V_{ID} = -1$ V		20	31	20	31	
I_{CC} Supply current	$V_O = 0, \text{ No load}$	25°C		6.9	9		6.9	9	mA
		Full range			9.4			9.4	

† Full range is 0°C to 70°C.



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TLE2142C operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142C			TLE2142AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega$	27	45		27	45		V/ μs
SR–	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		0.4			0.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$			15			15		nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$			10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = 10$, $f = 10\text{ kHz}$			0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$			6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$		5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = 1$, $C_L = 100\text{ pF}$			668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$			58°			58°		

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TLE2144C electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A [†]	TLE2144C			TLE2144AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _O = 2.5 V, V _{IC} = 2.5 V R _S = 50 Ω,	25°C	0.5 3.8		0.5 3		mV		
			Full range	4.4		3.6				
α _{VIO}	Temperature coefficient of input offset voltage		Full range	1.7		1.7		μV/°C		
I _{IO}	Input offset current		25°C	8 100		8 100		nA		
			Full range	150		150				
I _{IB}	Input bias current		25°C	–0.8 –2		–0.8 –2		μA		
		Full range	–2.1		–2.1					
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω	25°C	0 to 3	–0.3 to 3.2	0 to 3	–0.3 to 3.2	V		
			Full range	0 to 2.9		0 to 2.9				
V _{OH}	High-level output voltage	I _{OH} = –150 μA	25°C	3.9	4.1	3.9	4.1	V		
			Full range	3.8		3.8				
		I _{OH} = –1.5 mA	25°C	3.8	4	3.8	4			
			Full range	3.7		3.7				
		I _{OH} = –15 mA	25°C	3.4	3.7	3.4	3.7			
			Full range	3.4		3.4				
V _{OL}	Low-level output voltage	I _{OL} = 150 μA	25°C	75 125		75 125		mV		
			Full range	150		150				
		I _{OL} = 1.5 mA	25°C	150 225		150 225				
			Full range	250		250				
		I _{OL} = 15 mA	25°C	1.2 1.6		1.2 1.6		V		
			Full range	1.7		1.7				
A _{VD}	Large-signal differential voltage amplification	V _{CC} = ±2.5 V, R _L = 2 kΩ, V _O = 1 V to –1.5 V	25°C	50	95	50	95	V/mV		
			Full range	25		25				
r _i	Input resistance		25°C	70		70		MΩ		
c _i	Input capacitance		25°C	2.5		2.5		pF		
z _o	Open-loop output impedance	f = 1 MHz	25°C	30		30		Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , R _S = 50 Ω	25°C	85	118	85	118	dB		
			Full range	80		80				
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±2.5 V to ±15 V, R _S = 50 Ω	25°C	90	106	90	106	dB		
			Full range	85		85				
I _{CC}	Supply current	V _O = 2.5 V, V _{IC} = 2.5 V No load,	25°C	13.2 17.6		13.2 17.6		mA		
			Full range	18.5		18.5				

† Full range is 0°C to 70°C.

TLE2144C operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144C			TLE2144AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$	
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$	10.5			10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$,	$R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$	0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$	5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	57°			57°			

[†] R_L terminates at 2.5 V

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TLE2144C electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLE2144C			TLE2144AC			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _{IC} = 0, R _S = 50 Ω, V _O = 0		25°C	0.6		2.4	0.5		1.5	mV
	Full range			3.2		2.4					
α _{VIO}	Temperature coefficient of input offset voltage			Full range	1.7		1.7		μV/°C		
I _{IO}	Input offset current			25°C	7		100	7		100	nA
				Full range	150		150				
I _{IB}	Input bias current			25°C	−0.7		−1.5	−0.7		−1.5	μA
		Full range	−1.6		−1.6						
V _{ICR}	Common-mode input voltage range	R _S = 50 Ω		25°C	−15 to 13	−15.3 to 13.2	−15 to 13		−15.3 to 13.2	V	
				Full range	−15 to 12.9	−15.3 to 13.1	−15 to 12.9		−15.3 to 13.1		
V _{OM+}	Maximum positive peak output voltage swing	I _O = −150 μA		25°C	13.8	14.1	13.8		14.1	V	
				Full range	13.7		13.7				
		I _O = −1.5 mA		25°C	13.7	14	13.7		14		
				Full range	13.6		13.6				
		I _O = −15 mA		25°C	13.1	13.7	13.1		13.7		
				Full range	13		13				
V _{OM−}	Maximum negative peak output voltage swing	I _O = 150 μA		25°C	−14.7	−14.9	−14.7		−14.9	V	
				Full range	−14.6		−14.6				
		I _O = 1.5 mA		25°C	−14.5	−14.8	−14.5		−14.8		
				Full range	−14.4		−14.4				
		I _O = 15 mA		25°C	−13.4	−13.8	−13.4		−13.8		
				Full range	−13.3		−13.3				
A _{VD}	Large-signal differential voltage amplification	V _O = ±10 V		25°C	100	170	100		170	V/mV	
				Full range	75		75				
r _i	Input resistance	R _L = 2 kΩ		25°C	65		65		MΩ		
c _i	Input capacitance			25°C	2.5		2.5		pF		
z _o	Open-loop output impedance	f = 1 MHz		25°C	30		30		Ω		
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICRmin} , R _S = 50 Ω		25°C	85	108	85		108	dB	
				Full range	80		80				
k _{SVR}	Supply-voltage rejection ratio (ΔV _{CC±} /ΔV _{IO})	V _{CC±} = ±2.5 V to ±15 V, R _S = 50 Ω		25°C	90	106	90		106	dB	
				Full range	85		85				
I _{OS}	Short-circuit output current	V _O = 0	V _{ID} = 1 V	25°C	−25	−50	−25		−50	mA	
					20	31	20		31		
I _{CC}	Supply current	V _O = 0, No load		25°C	13.8		18	13.8		18	mA
				Full range	18.8		18.8				

† Full range is 0°C to 70°C.

TLE2144C operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144C			TLE2144AC			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 500\text{ pF}$		27	45		27	45	V/ μ s	
SR –	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%	0.34			0.34			μ s
			To 0.01%	0.4			0.4			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μ V
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.89			1.89			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.47			0.47			
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$	0.01%			0.01%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	6			6			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,	5.9			5.9			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	668			668			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	58°			58°			

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TLE2141I electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141I			TLE2141AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	225	1400		200	1000		μV
		Full range			1900			1500	
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range			200			200	
I_{IB} Input bias current		25°C	-0.8	-2		-0.8	-2		μA
		Full range			-2.2			-2.2	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	-0.3 to 3.2		0 to 3	-0.3 to 3.2		V
		Full range	0 to 2.7	-0.3 to 2.9		0 to 2.7	-0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.2	3.7		3.2	3.7		
	$I_{OH} = -100\ \mu\text{A}$	Full range	3.8			3.8			
	$I_{OH} = -1\text{ mA}$		3.7			3.7			
	$I_{OH} = -10\text{ mA}$		3.3			3.3			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\ \mu\text{A}$		150	225		150	225		V
	$I_{OL} = 15\text{ mA}$		1.2	1.6		1.2	1.6		
	$I_{OL} = 100\ \mu\text{A}$	Full range		175			175		mV
	$I_{OL} = 1\text{ mA}$			225			225		
	$I_{OL} = 10\text{ mA}$			1.4			1.4		V
A_{VD} Large-signal differential voltage amplification	$V_{CC} = \pm 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_O = 1\text{ V to } -1.5\text{ V}$	25°C	50	220		50	220		V/mV
		Full range	10			10			
r_i Input resistance		25°C		70			70		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C	3.4	4.4		3.4	4.4		mA
		Full range		4.6			4.6		

† Full range is -40°C to 105°C .

TLE2141I operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141I			TLE2141AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\ \Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $R_L = 2\text{ k}\Omega^\dagger$, $A_{VD} = 2$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}^\dagger$		5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$ $f = 100\text{ kHz}$		5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $R_L = 2\text{ k}\Omega^\dagger$, $A_{VD} = 1$, $C_L = 100\text{ pF}^\dagger$		660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}^\dagger$		57°			57°			

[†] R_L and C_L terminated to 2.5 V.

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TLE2141I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141I			TLE2141AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega, V_O = 0$	25°C	200	900		175	500		μV
		Full range		1500			1000		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		200			200		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.7			–1.7		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.1	13.7		13.1	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.1			13.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	450		100	450		V/mV
		Full range	40			40			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0$, No load	25°C	3.5	4.5		3.5	4.5		mA
		Full range		4.7			4.7		

† Full range is $-40^\circ C$ to $105^\circ C$.



TLE2141I operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141I			TLE2141AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega$	27	45		27	45		V/ μs
SR–	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		0.4			0.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$,	$f = 10\text{ Hz}$		15			15		nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$,	$f = 1\text{ kHz}$		10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$		0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$		6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$		5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$		58°			58°		

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TLE2142I electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142I			TLE2142AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	220	1900		220	1500		μV
		Full range		2400			2000		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		200			200		
I_{IB} Input bias current		25°C	-0.8	-2		-0.8	-2		μA
		Full range		-2.2			-2.2		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	-0.3 to 3.2		0 to 3	-0.3 to 3.2		V
		Full range	0 to 2.7	-0.3 to 2.9		0 to 2.7	-0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.4	3.7		3.4	3.7		
	$I_{OH} = 100\ \mu\text{A}$	Full range	3.8			3.8			
	$I_{OH} = 1\text{ mA}$		3.7			3.7			
	$I_{OH} = 10\text{ mA}$		3.5			3.5			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\text{ mA}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.4		1.2	1.4		
	$I_{OL} = 100\ \mu\text{A}$	Full range	175			175			mV
	$I_{OL} = 1\text{ mA}$		225			225			
	$I_{OL} = 10\text{ mA}$		1.2			1.2			
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $V_O = 1\text{ V to } -1.5\text{ V}$ $R_L = 2\text{ k}\Omega$	25°C	50	220		50	220		V/mV
		Full range	10			10			
r_i Input resistance		25°C	70			70			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C	6.6	8.8		6.6	8.8		mA
		Full range		9.2			9.2		

† Full range is -40°C to 105°C.

TLE2142I operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142I			TLE2142AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$	$R_L = 2\text{ k}\Omega^\dagger$	45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$,	$f = 10\text{ Hz}$	15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$,	$f = 1\text{ kHz}$	10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$,	$R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$	0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,	5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$	660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$,	$C_L = 100\text{ pF}$	57°			57°			

[†] R_L terminates at 2.5 V.

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TLE2142I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142I			TLE2142I			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega, V_O = 0$	25°C	290	1200		275	750		μV
		Full range		1800			1400		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		200			200		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.7			–1.7		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.3	13.7		13.3	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.3			13.3			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	450		100	450		V/mV
		Full range	40			40			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$	25°C	85	108		85	108		dB
	$R_S = 50 \Omega$	Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, \text{ No load}$	25°C	6.9	9		6.9	9		mA
		Full range		9.4			9.4		

† Full range is $-40^\circ C$ to $105^\circ C$.



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TLE2142I operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142I			TLE2142AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 500\text{ pF}$		30	45		30	45	V/ μs	
SR –	Negative slew rate			30	42		30	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%	0.34			0.34			μs
			To 0.01%	0.4			0.4			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.89			1.89			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.47			0.47			
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$	0.01%			0.01%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	6			6			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,	5.9			5.9			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	668			668			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	58°			58°			

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TLE2144I electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2144I			TLE2144AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50\ \Omega, V_O = 0$	25°C	0.5	3.8		0.5	3		mV
		Full range			4.8			4	
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range			200			200	
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range			–2.2			–2.2	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.7	–0.3 to 2.9		0 to 2.7	–0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\ \text{mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\ \text{mA}$		3.4	3.7		3.4	3.7		
	$I_{OH} = 100\ \mu\text{A}$	Full range	3.8			3.8			
	$I_{OH} = 1\ \text{mA}$		3.7			3.7			
	$I_{OH} = 10\ \text{mA}$		3.5			3.5			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\ \mu\text{A}$		150	225		150	225		
	$I_{OL} = 15\ \text{mA}$		1.2	1.6		1.2	1.6		V
	$I_{OL} = 100\ \mu\text{A}$	Full range		175			175		mV
	$I_{OL} = 1\ \text{mA}$			225			225		
	$I_{OL} = 10\ \text{mA}$			1.4			1.4		V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\ \text{V}, R_L = 2\ \text{k}\Omega, V_O = 1\ \text{V to } -1.5\ \text{V}$	25°C	50	95		50	95		V/mV
		Full range	10			10			
r_i Input resistance		25°C		70			70		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\ \text{MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\ \text{V to } \pm 15\ \text{V}, R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\ \text{V}, V_{IC} = 2.5\ \text{V}$ No load,	25°C	13.2	17.6		13.2	17.6		mA
		Full range		18.4			18.4		

† Full range is -40°C to 105°C .

TLE2144I operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144I			TLE2144AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$ $R_L = 2\text{ k}\Omega^\dagger$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$		5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		57°			57°			

[†] R_L terminates at 2.5 V

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TLE2144I electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2144I			TLE2144AI			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0,$ $V_O = 0$ $R_S = 50 \Omega$	25°C	0.6	2.4		0.5	1.5		mV
		Full range			3.2			2.8	
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		200			200		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.7			–1.7		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.1	13.7		13.1	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.1			13.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	170		100	170		V/mV
		Full range	40			40			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin},$ $R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$ $\frac{V_{ID} = 1$ V $V_{ID} = -1$ V	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0,$ No load	25°C	13.8	18		13.8	18		mA
		Full range		18.8			18.8		

† Full range is $-40^\circ C$ to $105^\circ C$.



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TLE2144I operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144I			TLE2144AI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 500\text{ pF}$		27	45		27	45	V/ μs	
SR –	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%	0.34		0.34		μs		
			To 0.01%	0.4		0.4				
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$,	$f = 10\text{ Hz}$	15		15		nV/ $\sqrt{\text{Hz}}$		
		$R_S = 20\text{ }\Omega$,	$f = 1\text{ kHz}$	10.5		10.5				
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48		0.48		μV		
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51		0.51				
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.89		1.89		pA/ $\sqrt{\text{Hz}}$		
		$f = 1\text{ kHz}$		0.47		0.47				
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$	0.01%		0.01%				
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	6		6		MHz		
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,	5.9		5.9		MHz		
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	668		668		kHz		
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$	58°		58°				

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TLE2141M electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141M			TLE2141AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$ $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	225	1400		200	1000		μV
		Full range		2100			1700		
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range		–2.3			–2.3		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.7	–0.3 to 2.9		0 to 2.7	–0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.2	3.7		3.2	3.7		
	$I_{OH} = -100\ \mu\text{A}$	Full range	3.75			3.75			
	$I_{OH} = -1\text{ mA}$		3.65			3.65			
	$I_{OH} = -10\text{ mA}$		3.25			3.25			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\ \mu\text{A}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.4		1.2	1.4		V
	$I_{OL} = 100\ \mu\text{A}$	Full range	200			200			mV
	$I_{OL} = 1\text{ mA}$		250			225			
	$I_{OL} = 10\text{ mA}$		1.25			1.25			V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_O = 1\text{ V to } -1.5\text{ V}$	25°C	50	220		50	220		V/mV
		Full range	5			5			
r_i Input resistance		25°C		70			70		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C	3.4	4.4		3.4	4.4		mA
		Full range		4.6			4.6		

† Full range is -55°C to 125°C .

TLE2141M operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141M			TLE2141AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}^\dagger$		5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$		5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$		660			660			kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}^\dagger$		57°			57°			

$^\dagger R_L$ and C_L terminated to 2.5 V.

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PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2141M			TLE2141AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega$	25°C	200	900		175	500		μV
		Full range		1700			1200		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.8			–1.8		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.1	13.7		13.1	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.1			13.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	450		100	450		V/mV
		Full range	20			20			
r_i Input resistance		25°C	65			65			M Ω
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, V_{IC} = 2.5$ V No load,	25°C	3.5	4.5		3.5	4.5		mA
		Full range		4.7			4.7		

† Full range is $-55^\circ C$ to $125^\circ C$.

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TLE2141M operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2141M			TLE2141AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	A _{VD} = − 1, R _L = 2 kΩ, C _L = 100 pF		27	45		27	45	V/μs	
SR −	Negative slew rate			27	42		27	42		
t _s	Settling time	A _{VD} = − 1, 10-V step	To 0.1%	0.34		0.34		μs		
			To 0.01%	0.4		0.4				
V _n	Equivalent input noise voltage	R _S = 20 Ω, f = 10 Hz		15		15		nV/√Hz		
		R _S = 20 Ω, f = 1 kHz		10.5		10.5				
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		0.48		0.48		μV		
		f = 0.1 Hz to 10 Hz		0.51		0.51				
I _n	Equivalent input noise current	f = 10 Hz		1.89		1.89		pA/√Hz		
		f = 1 kHz		0.47		0.47				
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, A _{VD} = 10,	R _L = 2 kΩ, f = 10 kHz	0.01%		0.01%				
B ₁	Unity-gain bandwidth	R _L = 2 kΩ,	C _L = 100 pF	6		6		MHz		
	Gain-bandwidth product	R _L = 2 kΩ, f = 100 kHz	C _L = 100 pF,	5.9		5.9		MHz		
B _{OM}	Maximum output-swing bandwidth	V _{O(PP)} = 20 V, A _{VD} = 1,	R _L = 2 kΩ, C _L = 100 pF	668		668		kHz		
φ _m	Phase margin at unity gain	R _L = 2 kΩ,	C _L = 100 pF	58°		58°				

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TLE2142M electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142M			TLE2142AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C		220	1900		200	1500	μV
		Full range			2600			2200	
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C		8	100		8	100	nA
		Full range			200			200	
I_{IB} Input bias current		25°C		-0.8	-2		-0.8	-2	μA
		Full range			-2.3			-2.3	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	-0.3 to 3.2		0 to 3	-0.3 to 3.2		V
		Full range	0 to 2.7	-0.3 to 2.9		0 to 2.7	-0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.4	3.7		3.4	3.7		
	$I_{OH} = 100\ \mu\text{A}$	Full range	3.75			3.75			
	$I_{OH} = 1\text{ mA}$		3.65			3.65			
	$I_{OH} = 10\text{ mA}$		3.45			3.45			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\text{ mA}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.4		1.2	1.4		V
	$I_{OL} = 100\ \mu\text{A}$	Full range	200			200			mV
	$I_{OL} = 1\text{ mA}$		250			250			
	$I_{OL} = 10\text{ mA}$		1.25			1.25			V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $V_O = 1\text{ V to } -1.5\text{ V}$ $R_L = 2\text{ k}\Omega$	25°C	50	220		50	220		V/mV
		Full range	5			5			
r_i Input resistance		25°C		70			70		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C		6.6	8.8		6.6	8.8	mA
		Full range			9.2			9.2	

† Full range is -55°C to 125°C.

TLE2142M operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142M			TLE2142AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $R_L = 2\text{ k}\Omega^\dagger$, $A_{VD} = 2$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $f = 100\text{ kHz}$		5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $R_L = 2\text{ k}\Omega^\dagger$, $A_{VD} = 1$, $C_L = 100\text{ pF}$		660			660			kHz
ϕ_m	Phase margin	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		57°			57°			

$^\dagger R_L$ terminates at 2.5 V.

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TLE2142M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2142M			TLE2142AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, \quad R_S = 50 \, \Omega$	25°C	290	1200		275	750		μV
		Full range		2000			1600		
α_{VIO} Temperature coefficient of input offset voltage		Full range	1.7			1.7			$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.8			–1.8		
V_{ICR} Common-mode input voltage range	$R_S = 50 \, \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \, \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5 \, mA$		13.7	14		13.7	14		
	$I_O = -15 \, mA$		13.3	13.7		13.3	13.7		
	$I_O = -100 \, \mu A$	Full range	13.7			13.7			
	$I_O = -1 \, mA$		13.6			13.6			
	$I_O = -10 \, mA$		13.3			13.3			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \, \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5 \, mA$		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15 \, mA$		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \, \mu A$	Full range	–14.6			–14.6			
	$I_O = 1 \, mA$		–14.5			–14.5			
	$I_O = 10 \, mA$		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10 \, V, \quad R_L = 2 \, k\Omega$	25°C	100	450		100	450		V/mV
		Full range	20			20			
r_i Input resistance		25°C	65			65			$M\Omega$
c_i Input capacitance		25°C	2.5			2.5			pF
z_o Open-loop output impedance	$f = 1 \, MHz$	25°C	30			30			Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, \quad R_S = 50 \, \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5 \, V$ to $\pm 15 \, V, \quad R_S = 50 \, \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, \quad V_{IC} = 2.5 \, V$	25°C	6.9	9		6.9	9		mA
		Full range		9.4			9.4		

† Full range is $-55^\circ C$ to $125^\circ C$.

TLE2142M operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2142M			TLE2142AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	R _L = 2 kΩ, A _{VD} = − 1, C _L = 100 pF		27	45		27	45		V/μs
SR −	Negative slew rate			27	42		27	42		
t _s	Settling time	A _{VD} = − 1, 10-V step	To 0.1%	0.34			0.34			μs
			To 0.01%	0.4			0.4			
V _n	Equivalent input noise voltage	R _S = 20 Ω, f = 10 Hz		15			15			nV/√Hz
		R _S = 20 Ω, f = 1 kHz		10.5			10.5			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		0.48			0.48			μV
		f = 0.1 Hz to 10 Hz		0.51			0.51			
I _n	Equivalent input noise current	f = 10 Hz		1.89			1.89			pA/√Hz
		f = 1 kHz		0.47			0.47			
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 20 V, R _L = 2 kΩ, A _{VD} = 10, f = 10 kHz	0.01%			0.01%				
B ₁	Unity-gain bandwidth	R _L = 2 kΩ, C _L = 100 pF	6			6			MHz	
	Gain-bandwidth product	R _L = 2 kΩ, C _L = 100 pF, f = 100 kHz	5.9			5.9			MHz	
B _{OM}	Maximum output-swing band-width	V _{O(PP)} = 20 V, R _L = 2 kΩ, A _{VD} = 1, C _L = 100 pF	668			668			kHz	
φ _m	Phase margin at unity gain	R _L = 2 kΩ, C _L = 100 pF	58°			58°				

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TLE2144M electrical characteristics at specified free-air temperature, $V_{CC} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2144M			TLE2144AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ $R_S = 50\ \Omega$	25°C	0.5	3.8		0.5	3		mV
		Full range		5.2			4.4		
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C	8	100		8	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.8	–2		–0.8	–2		μA
		Full range		–2.3			–2.3		
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.7	–0.3 to 2.9		0 to 2.7	–0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.4	3.7		3.4	3.7		
	$I_{OH} = 100\ \mu\text{A}$	Full range	3.75			3.75			
	$I_{OH} = 1\text{ mA}$		3.65			3.65			
	$I_{OH} = 10\text{ mA}$		3.45			3.45			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C	75	125		75	125		mV
	$I_{OL} = 1.5\ \mu\text{A}$		150	225		150	225		
	$I_{OL} = 15\text{ mA}$		1.2	1.6		1.2	1.6		V
	$I_{OL} = 100\ \mu\text{A}$	Full range	200			200			mV
	$I_{OL} = 1\text{ mA}$		250			250			
	$I_{OL} = 10\text{ mA}$		1.45			1.45			V
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $V_O = 1\text{ V to } -1.5\text{ V}$ $R_L = 2\text{ k}\Omega$	25°C	50	95		50	95		V/mV
		Full range	5			5			
r_i Input resistance		25°C		70			70		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	25°C	85	118		85	118		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, $V_{IC} = 2.5\text{ V}$ No load,	25°C	13.2	17.6		13.2	17.6		mA
		Full range		18.4			18.4		

† Full range is -55°C to 125°C .

TLE2144M operating characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144M			TLE2144AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR +	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^\dagger$, $C_L = 500\text{ pF}$		45			45			V/ μs
SR –	Negative slew rate			42			42			
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16			0.16			μs
			To 0.01%	0.22			0.22			
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$, $f = 10\text{ Hz}$		15			15			nV/ $\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$, $f = 1\text{ kHz}$		10.5			10.5			
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$		0.48			0.48			μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$		0.51			0.51			
I_n	Equivalent input noise current	$f = 10\text{ Hz}$		1.92			1.92			pA/ $\sqrt{\text{Hz}}$
		$f = 1\text{ kHz}$		0.5			0.5			
THD + N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $A_{VD} = 2$, $R_L = 2\text{ k}\Omega^\dagger$, $f = 10\text{ kHz}$		0.0052%			0.0052%			
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		5.9			5.9			MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$, $f = 100\text{ kHz}$		5.8			5.8			MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega^\dagger$		660			660			kHz
ϕ_m	Phase margin	$R_L = 2\text{ k}\Omega^\dagger$, $C_L = 100\text{ pF}$		57°			57°			

[†] R_L terminates at 2.5 V

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TLE2144M electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15$ V (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLE2144M			TLE2144AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0, R_S = 50 \Omega$	25°C	0.6	2.4		0.5	1.5		mV
		Full range			4			3.2	
α_{VIO} Temperature coefficient of input offset voltage		Full range		1.7			1.7		$\mu V/^\circ C$
I_{IO} Input offset current		25°C	7	100		7	100		nA
		Full range		250			250		
I_{IB} Input bias current		25°C	–0.7	–1.5		–0.7	–1.5		μA
		Full range		–1.8			–1.8		
V_{ICR} Common-mode input voltage range	$R_S = 50 \Omega$	25°C	–15 to 13	–15.3 to 13.2		–15 to 13	–15.3 to 13.2		V
		Full range	–15 to 12.7	–15.3 to 12.9		–15 to 12.7	–15.3 to 12.9		
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150 \mu A$	25°C	13.8	14.1		13.8	14.1		V
	$I_O = -1.5$ mA		13.7	14		13.7	14		
	$I_O = -15$ mA		13.1	13.7		13.1	13.7		
	$I_O = -100 \mu A$	Full range	13.7			13.7			
	$I_O = -1$ mA		13.6			13.6			
	$I_O = -10$ mA		13.1			13.1			
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150 \mu A$	25°C	–14.7	–14.9		–14.7	–14.9		V
	$I_O = 1.5$ mA		–14.5	–14.8		–14.5	–14.8		
	$I_O = 15$ mA		–13.4	–13.8		–13.4	–13.8		
	$I_O = 100 \mu A$	Full range	–14.6			–14.6			
	$I_O = 1$ mA		–14.5			–14.5			
	$I_O = 10$ mA		–13.4			–13.4			
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10$ V, $R_L = 2$ k Ω	25°C	100	170		100	170		V/mV
		Full range	20			20			
r_i Input resistance		25°C		65			65		M Ω
c_i Input capacitance		25°C		2.5			2.5		pF
z_o Open-loop output impedance	$f = 1$ MHz	25°C		30			30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}, R_S = 50 \Omega$	25°C	85	108		85	108		dB
		Full range	80			80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5$ V to ± 15 V, $R_S = 50 \Omega$	25°C	90	106		90	106		dB
		Full range	85			85			
I_{OS} Short-circuit output current	$V_O = 0$	25°C	–25	–50		–25	–50		mA
			20	31		20	31		
I_{CC} Supply current	$V_O = 0, V_{IC} = 2.5$ V	25°C		13.8	18		13.8	18	mA
		Full range			18.8			18.8	

† Full range is $-55^\circ C$ to $125^\circ C$



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TLE2144M operating characteristics, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS		TLE2144M			TLE2144AM			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
SR+	Positive slew rate	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	$A_{VD} = -1$,	27	45		27	45		$\text{V}/\mu\text{s}$
SR–	Negative slew rate			27	42		27	42		
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%		0.34			0.34		μs
			To 0.01%		.4			.4		
V_n	Equivalent input noise voltage	$R_S = 20\text{ }\Omega$,	$f = 10\text{ Hz}$		15			15		$\text{nV}/\sqrt{\text{Hz}}$
		$R_S = 20\text{ }\Omega$,	$f = 1\text{ kHz}$		10.5			10.5		
$V_{N(PP)}$	Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$			0.48			0.48		μV
		$f = 0.1\text{ Hz to }10\text{ Hz}$			0.51			0.51		
I_n	Equivalent input noise current	$f = 10\text{ Hz}$			1.89			1.89		$\text{pA}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$			0.47			0.47		
THD + N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 10$,	$R_L = 2\text{ k}\Omega$, $f = 10\text{ kHz}$		0.01%			0.01%		
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$		6			6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $f = 100\text{ kHz}$	$C_L = 100\text{ pF}$,		5.9			5.9		MHz
B_{OM}	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$,	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		668			668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$,	$C_L = 100\text{ pF}$		58°			58°		

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EXCALIBUR LOW-NOISE HIGH-SPEED

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TLE2141Y electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLE2141Y			UNIT
		MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $R_S = 50\ \Omega$, $V_O = 0$		200	1000	μV
I_{IO} Input offset current			7	100	nA
I_{IB} Input bias current			-0.7	-1.5	μA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	-15 to 13	-15.3 to 13.2		V
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150\ \mu\text{A}$	13.8	14.1		V
	$I_O = -1.5\text{ mA}$	13.7	14		
	$I_O = -15\text{ mA}$	13.3	13.7		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150\ \mu\text{A}$	-14.7	-14.9		V
	$I_O = 1.5\text{ mA}$	-14.5	-14.8		
	$I_O = 15\text{ mA}$	-13.4	-13.8		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$, $R_L = 2\text{ k}\Omega$	100	450		V/mV
r_i Input resistance			65		M Ω
c_i Input capacitance			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$		30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	80	108		dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	85	106		dB
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1\text{ V}$	-25	-50	mA
		$V_{ID} = -1\text{ V}$	20	31	
I_{CC} Supply current	$V_O = 0$, No load		3.5	4.5	mA

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TLE2142Y electrical characteristics at specified free-air temperature, $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	TLE2142Y			UNIT
			MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0$, $V_O = 0$ $R_S = 50\ \Omega$		150	875	μV
I_{IO}	Input offset current			7	100	nA
I_{IB}	Input bias current			-0.7	-1.5	μA
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$	-15 to 13	-15.3 to 13.2		V
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -150\ \mu\text{A}$	13.8	14.1		V
		$I_O = -1.5\text{ mA}$	13.7	14		
		$I_O = -15\text{ mA}$	13.3	13.7		
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 150\ \mu\text{A}$	-14.7	-14.9		V
		$I_O = 1.5\text{ mA}$	-14.5	-14.8		
		$I_O = 15\text{ mA}$	-13.4	-13.8		
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$, $R_L = 2\text{ k}\Omega$	100	450		V/mV
r_i	Input resistance			65		M Ω
c_i	Input capacitance			2.5		pF
z_o	Open-loop output impedance	$f = 1\text{ MHz}$		30		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	80	108		dB
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm} / \Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	85	106		dB
I_{OS}	Short-circuit output current	$V_O = 0$	$V_{ID} = 1\text{ V}$	-25	-50	mA
			$V_{ID} = -1\text{ V}$	20	31	
I_{CC}	Supply current	$V_O = 0$, No load		6.9	9	mA

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TLE2144Y electrical characteristics at $V_{CC\pm} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	TLE2144Y			UNIT
		MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$,		0.3	1.8	mV
I_{IO} Input offset current			7	100	nA
I_{IB} Input bias current			-0.7	-1.5	μA
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	-15 to 13	-15.3 to 13.2		V
V_{OM+} Maximum positive peak output voltage swing	$I_O = -150\ \mu\text{A}$	13.8	14.1		V
	$I_O = -1.5\text{ mA}$	13.7	14		
	$I_O = -15\text{ mA}$	13.3	13.7		
V_{OM-} Maximum negative peak output voltage swing	$I_O = 150\ \mu\text{A}$	-14.7	-14.9		V
	$I_O = 1.5\text{ mA}$	-14.5	-14.8		
	$I_O = 15\text{ mA}$	-13.4	-13.8		
A_{VD} Large-signal differential voltage amplification	$V_O = \pm 10\text{ V}$, $R_L = 2\text{ k}\Omega$	100	450		V/mV
r_i Input resistance			65		$\text{M}\Omega$
c_i Input capacitance			2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$		30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICRmin}$, $R_S = 50\ \Omega$	80	108		dB
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	85	106		dB
I_{OS} Short-circuit output current	$V_O = 0$	$V_{ID} = 1\text{ V}$	-25	-50	mA
		$V_{ID} = -1\text{ V}$	20	31	
I_{CC} Supply current	$V_O = 0$, No load		13.8	18	mA

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	Distribution	1, 2, 3
I_{IO}	Input offset current	vs Free-air temperature	4
I_{IB}	Input bias current	vs Common-mode input voltage vs Free-air temperature	5 6
V_{OM+}	Maximum positive peak output voltage	vs Supply voltage vs Free-air temperature vs Output current vs Settling time	7 8 9 11
V_{OM-}	Maximum negative peak output voltage	vs Supply voltage vs Free-air temperature vs Output current vs Settling time	7 8 10 11
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	12
V_{OH}	High-level output voltage	vs Output current	13
V_{OL}	Low-level output voltage	vs Output current	14
A_{VD}	Large-signal differential voltage amplification	vs Frequency vs Free-air temperature	15 16
z_o	Closed-loop output impedance	vs Frequency	17
I_{OS}	Short-circuit output current	vs Free-air temperature	18
$CMRR$	Common-mode rejection ratio	vs Frequency vs Free-air temperature	19 20
k_{SVR}	Supply-voltage rejection ratio	vs Frequency vs Free-air temperature	21 22
I_{CC}	Supply current	vs Supply voltage vs Free-air temperature	23 24
V_n	Equivalent input noise voltage	vs Frequency	25
V_n	Input noise voltage	Over a 10-second period	26
I_n	Noise current	vs Frequency	27
THD + N	Total harmonic distortion plus noise	vs Frequency	28
SR	Slew rate	vs Free-air temperature vs Load capacitance	29 30
Pulse response	Noninverting large signal	vs Time	31
	Inverting large signal	vs Time	32
	Small signal	vs Time	33
B_1	Unity-gain bandwidth	vs Load capacitance	34
	Gain margin	vs Load capacitance	35
ϕ_m	Phase margin	vs Load capacitance	36
	Phase shift	vs Frequency	15

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TYPICAL CHARACTERISTICS

**TLE2141
DISTRIBUTION OF
INPUT OFFSET VOLTAGE**

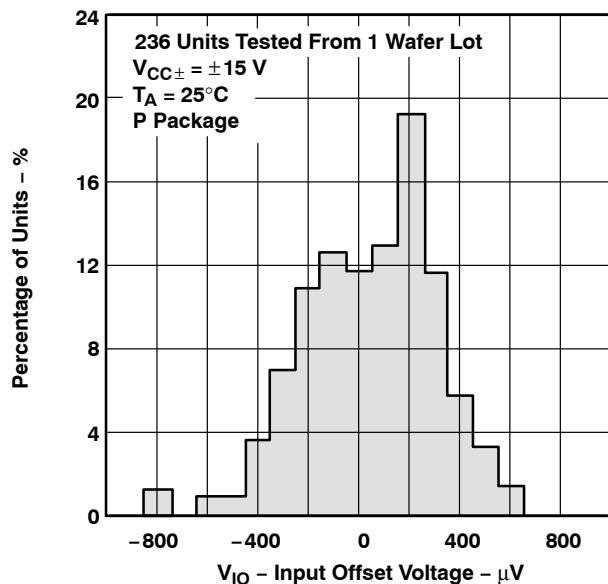


Figure 1

**TLE2142
DISTRIBUTION OF
INPUT OFFSET VOLTAGE**

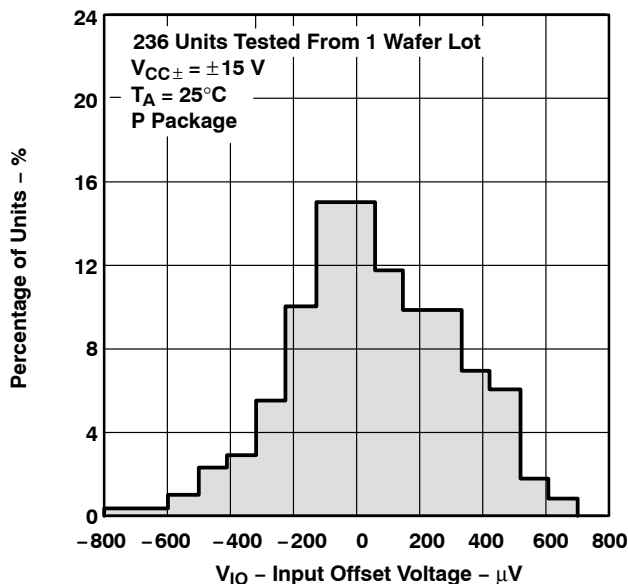


Figure 2

**TLE2144
DISTRIBUTION OF
INPUT OFFSET VOLTAGE**

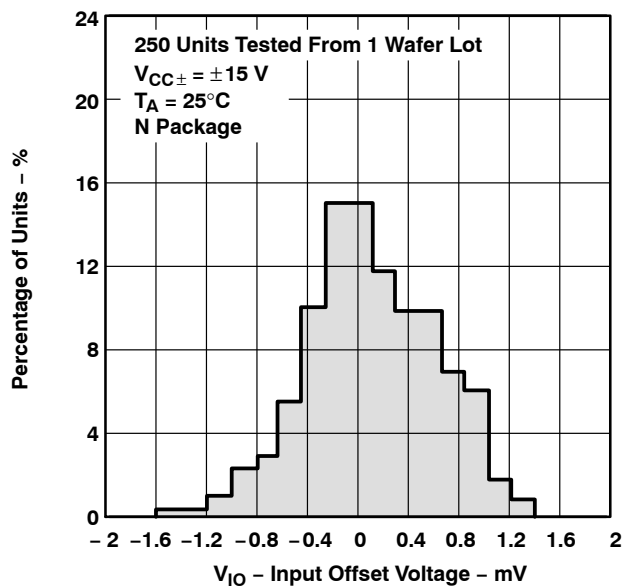


Figure 3

**INPUT OFFSET CURRENT[†]
vs
FREE-AIR TEMPERATURE**

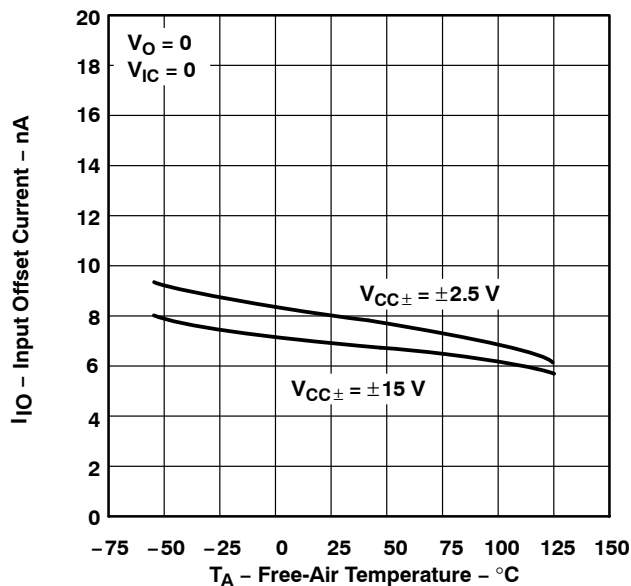
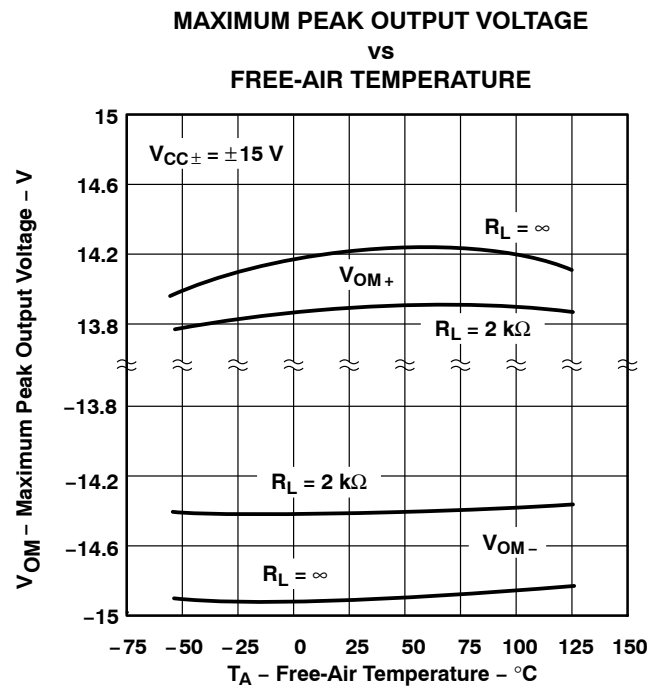
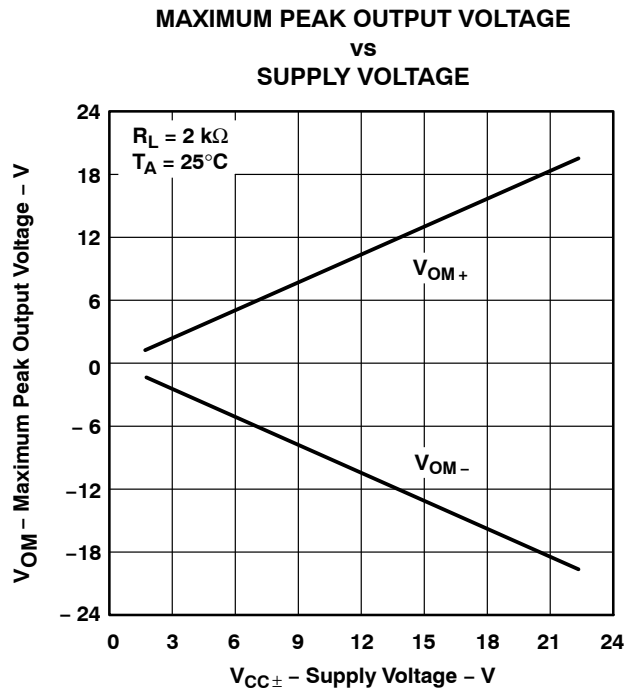
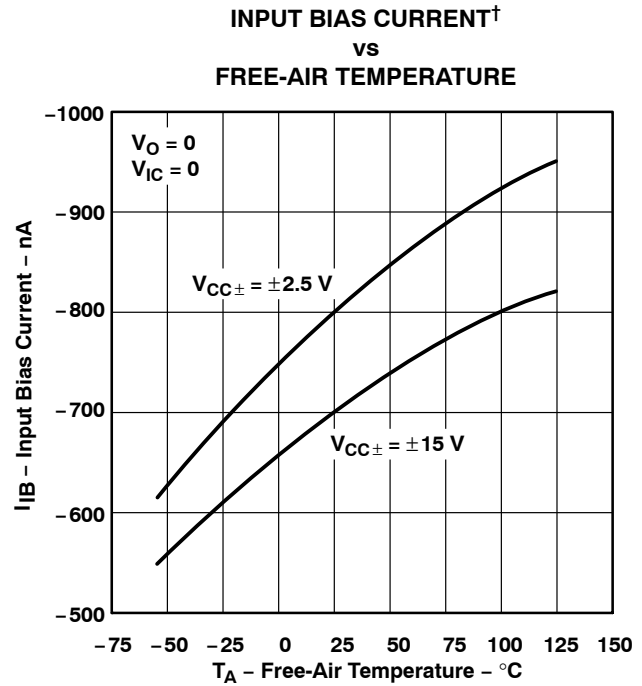
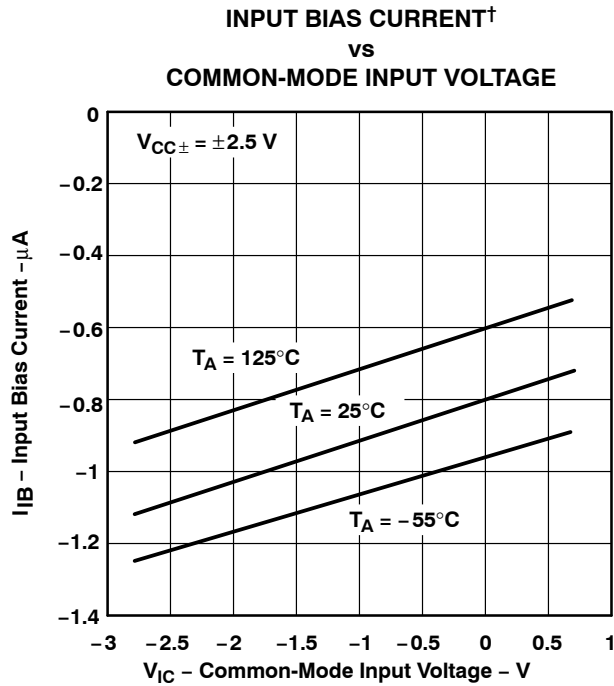


Figure 4

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS

MAXIMUM POSITIVE PEAK
OUTPUT VOLTAGE[†]
vs
OUTPUT CURRENT

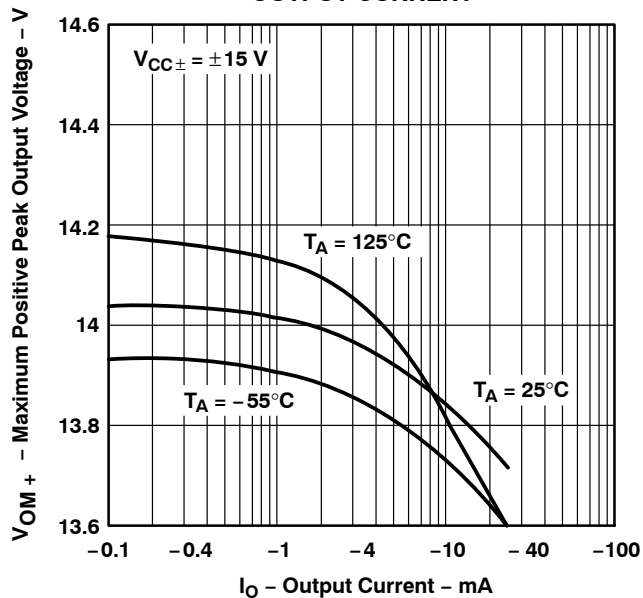


Figure 9

MAXIMUM NEGATIVE PEAK
OUTPUT VOLTAGE[†]
vs
OUTPUT CURRENT

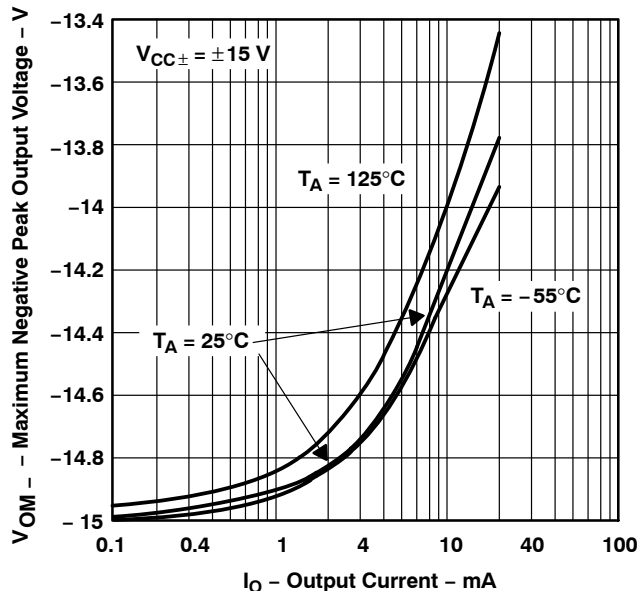


Figure 10

MAXIMUM PEAK OUTPUT VOLTAGE
vs
SETTLING TIME

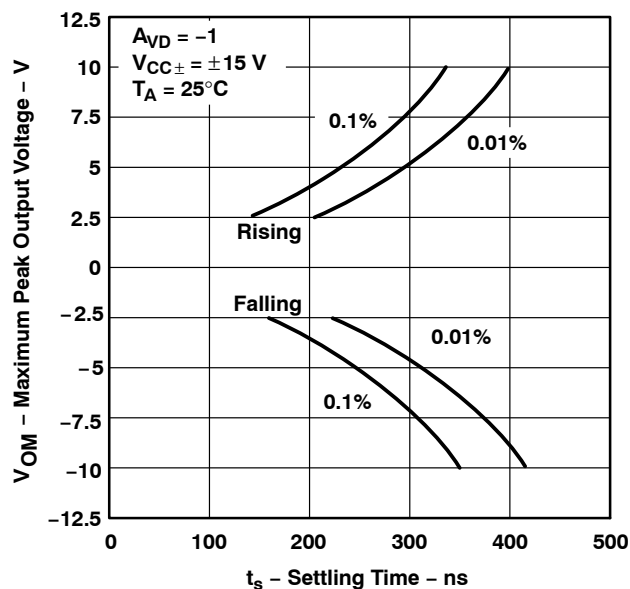


Figure 11

MAXIMUM PEAK-TO-PEAK
OUTPUT VOLTAGE[†]
vs
FREQUENCY

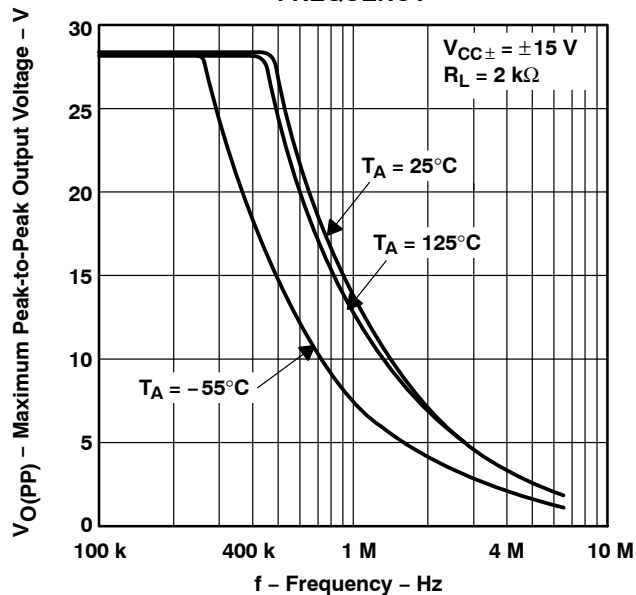
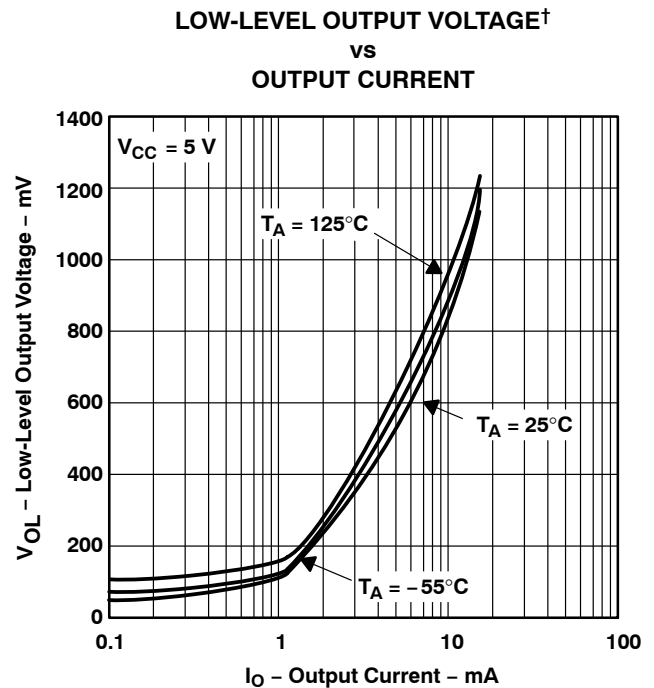
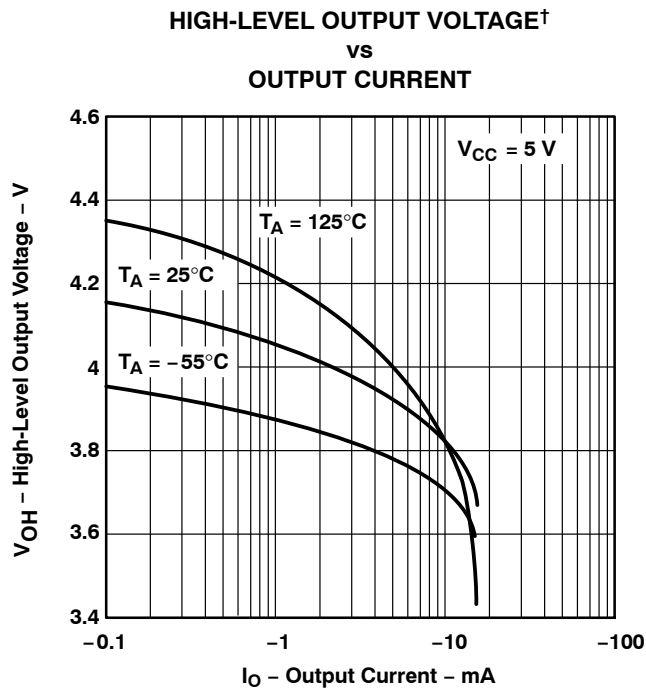


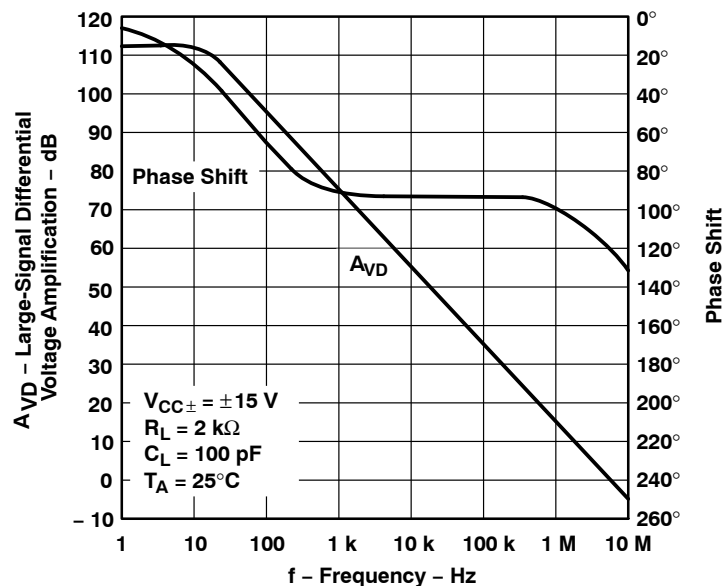
Figure 12

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS



LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT vs FREQUENCY



[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION[†]

vs

FREE-AIR TEMPERATURE

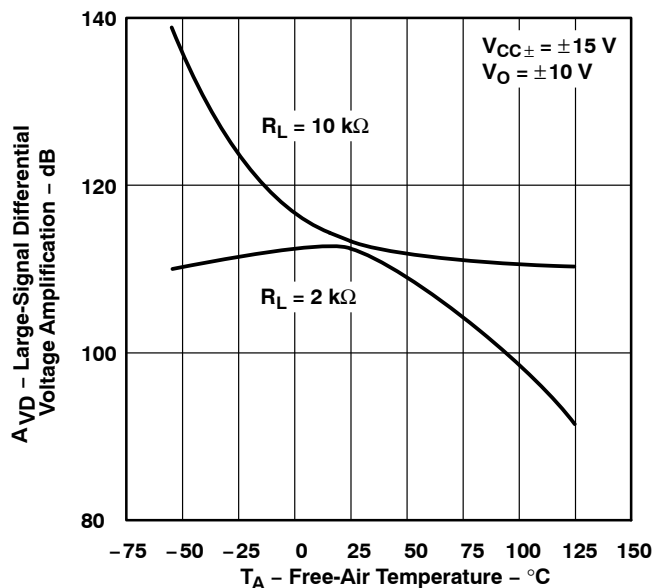


Figure 16

CLOSED-LOOP OUTPUT IMPEDANCE

vs

FREQUENCY

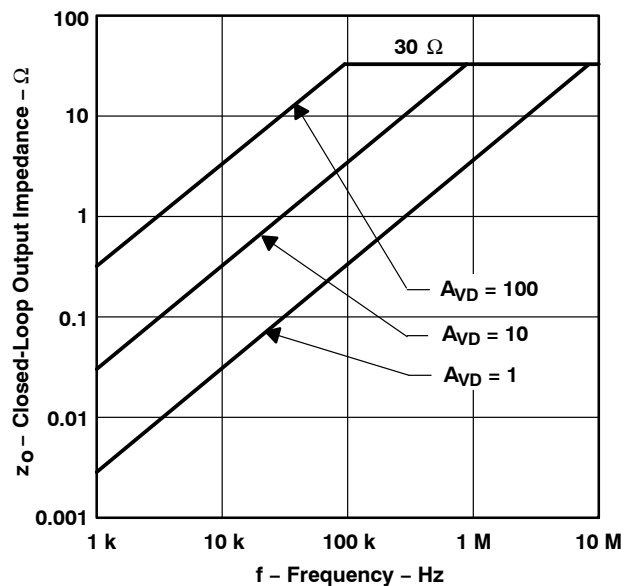


Figure 17

SHORT-CIRCUIT OUTPUT CURRENT[†]

vs

FREE-AIR TEMPERATURE

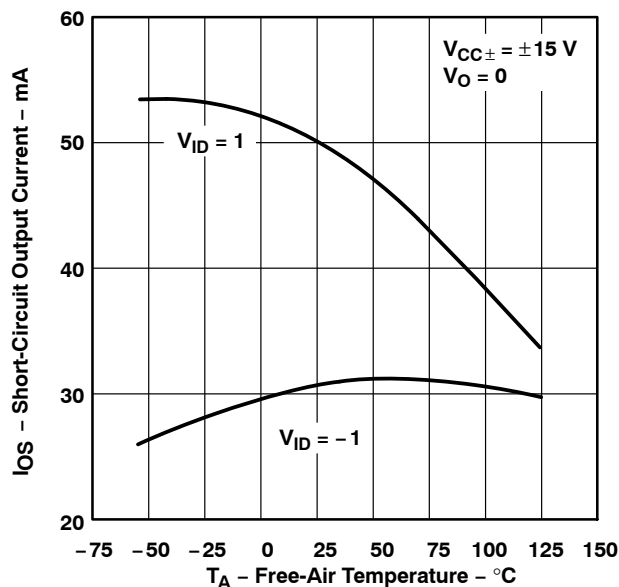


Figure 18

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

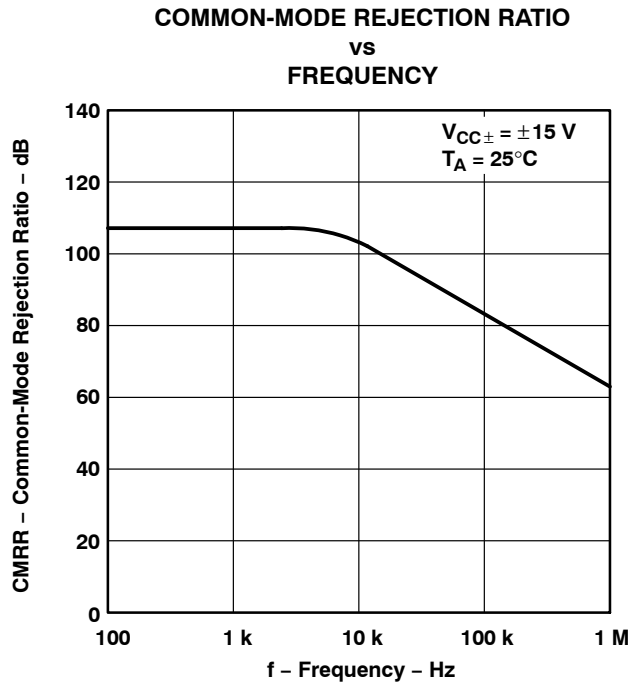


Figure 19

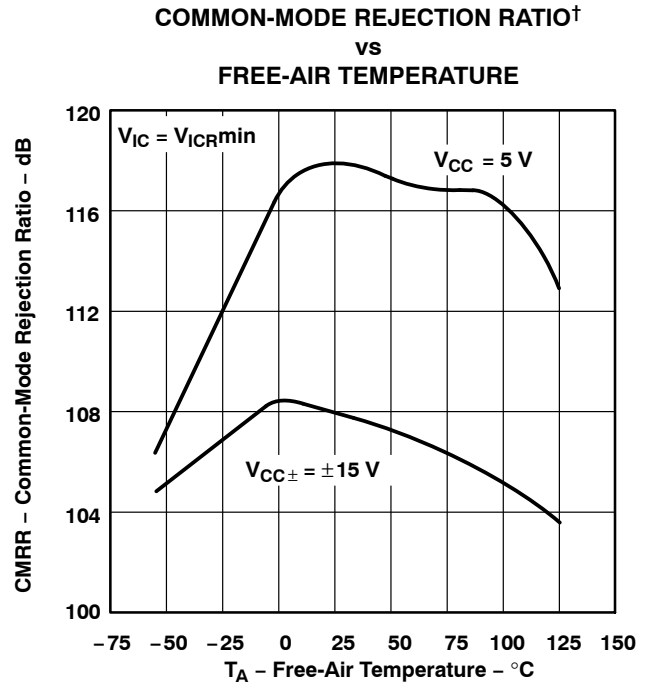


Figure 20

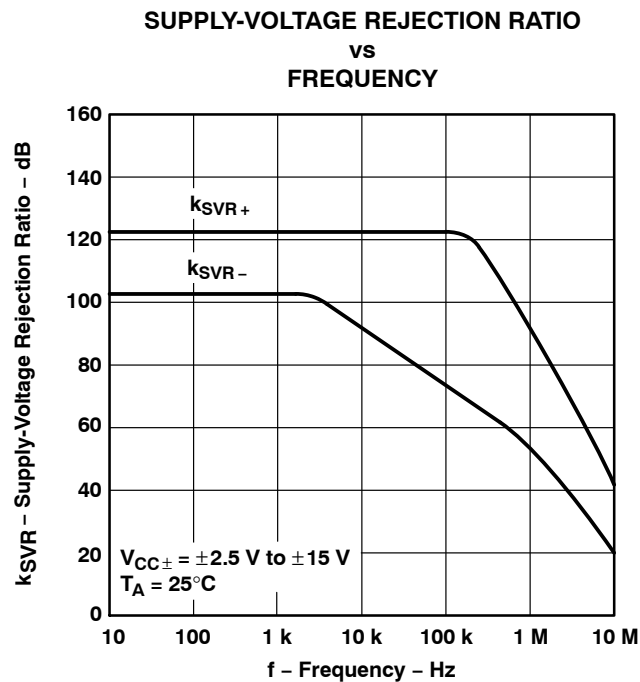


Figure 21

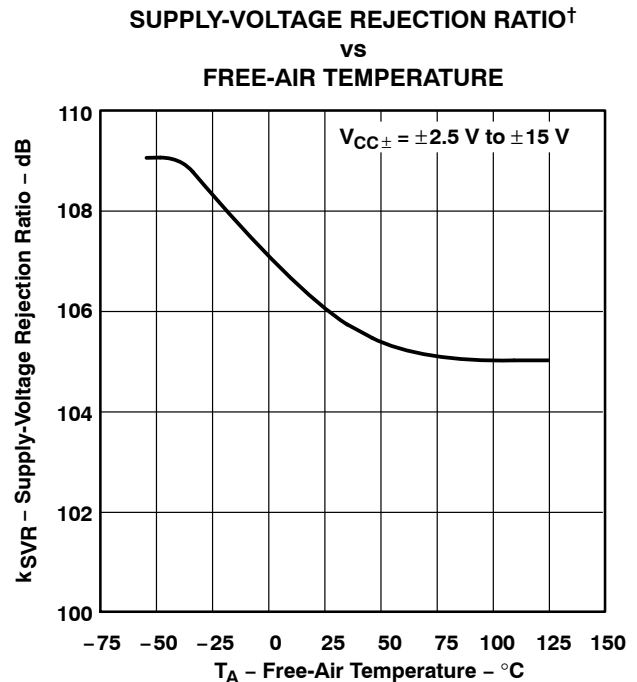


Figure 22

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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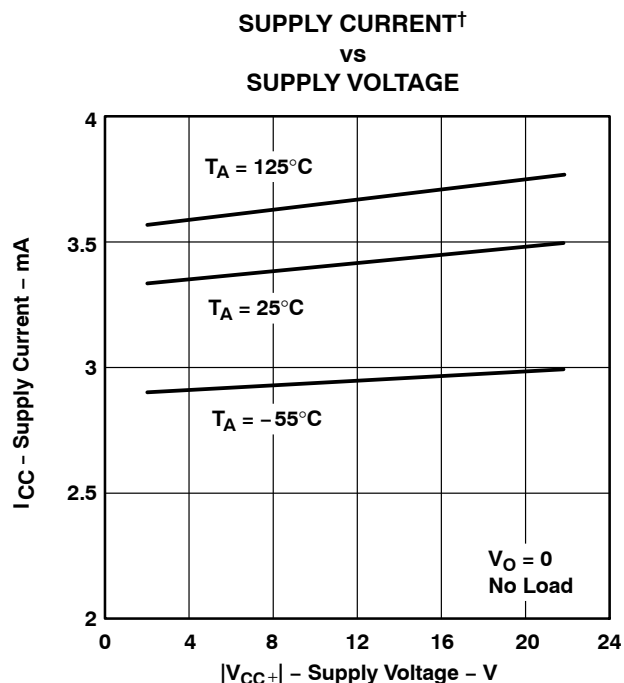


Figure 23

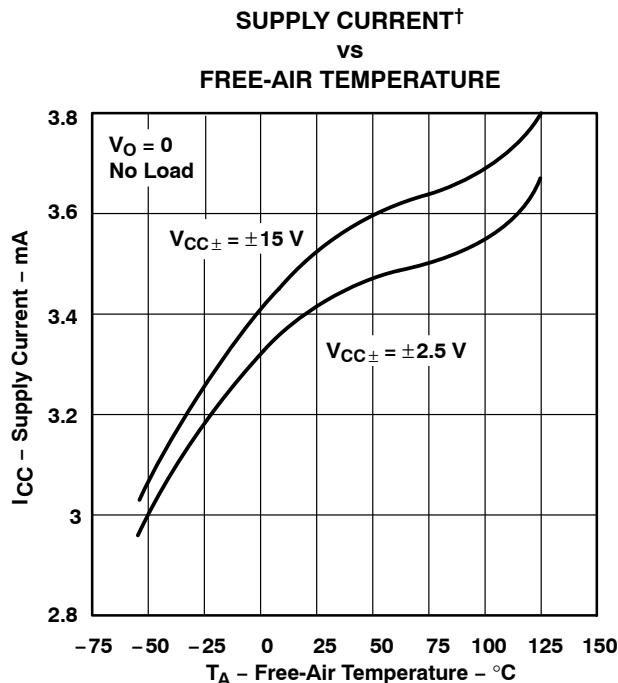


Figure 24

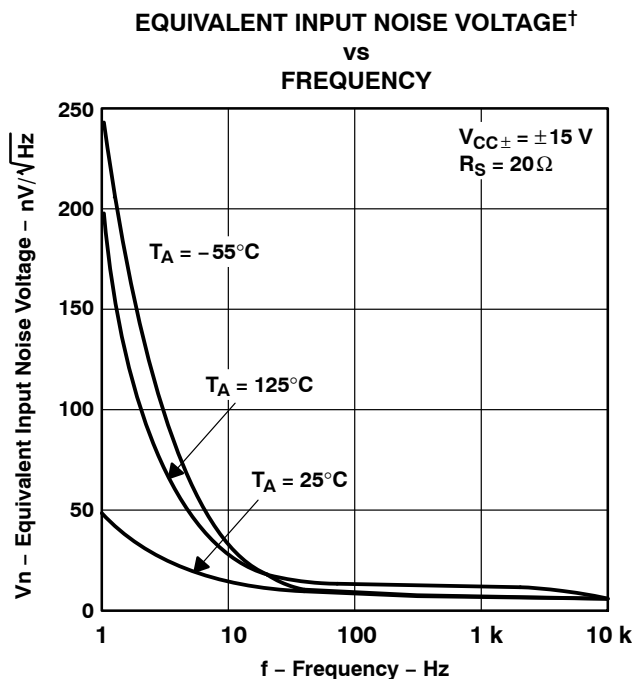


Figure 25

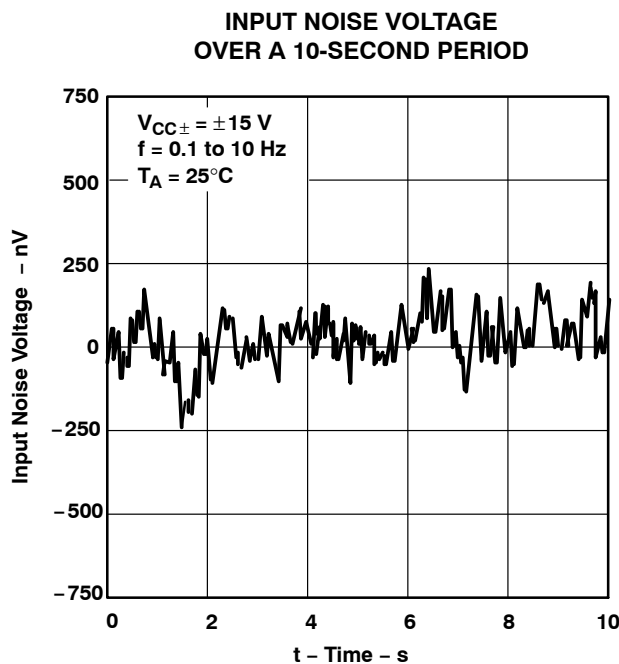


Figure 26

† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

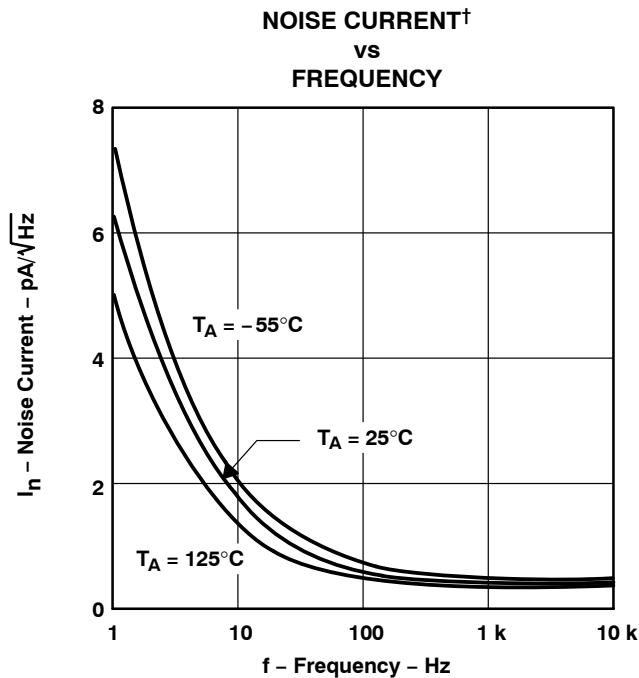


Figure 27

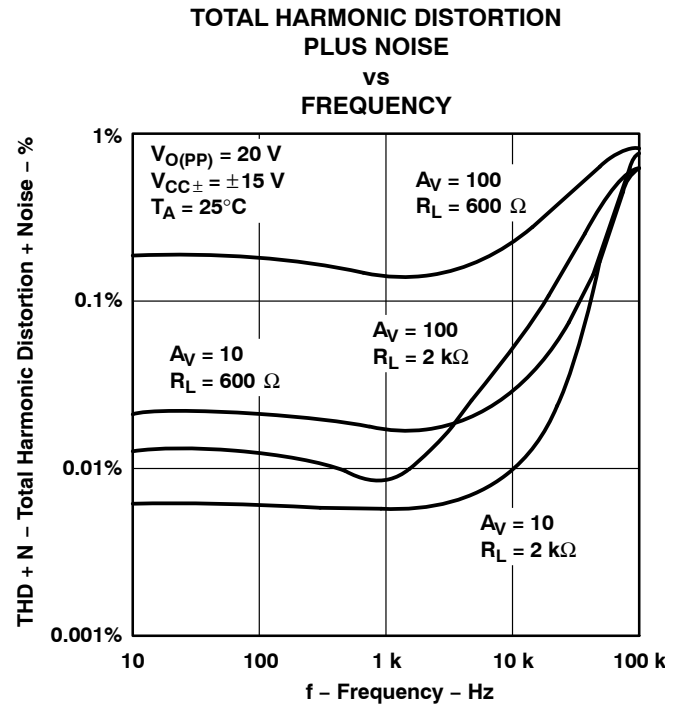


Figure 28

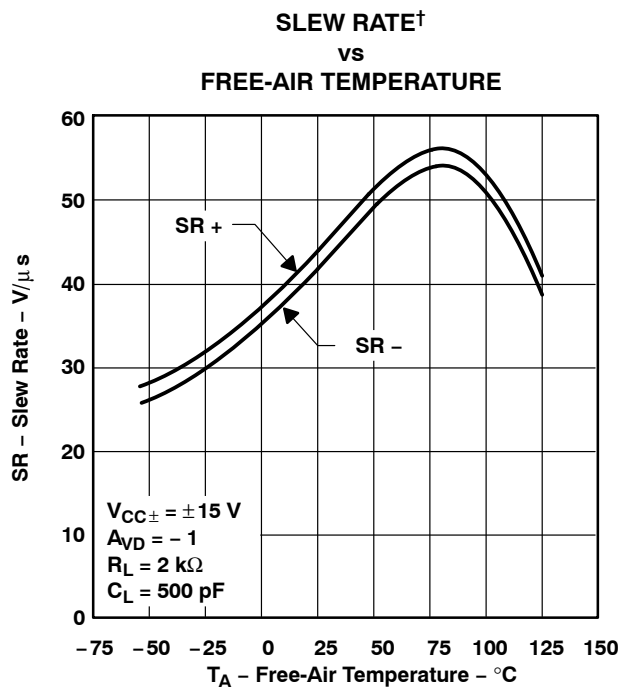


Figure 29

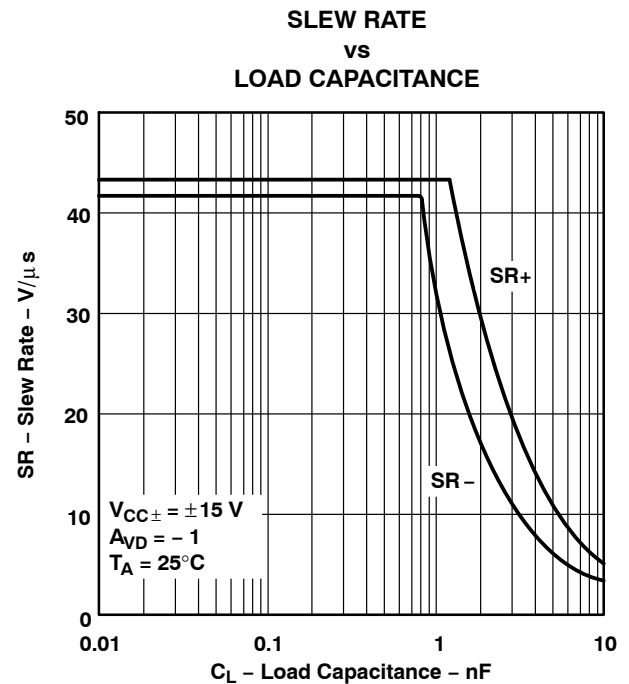


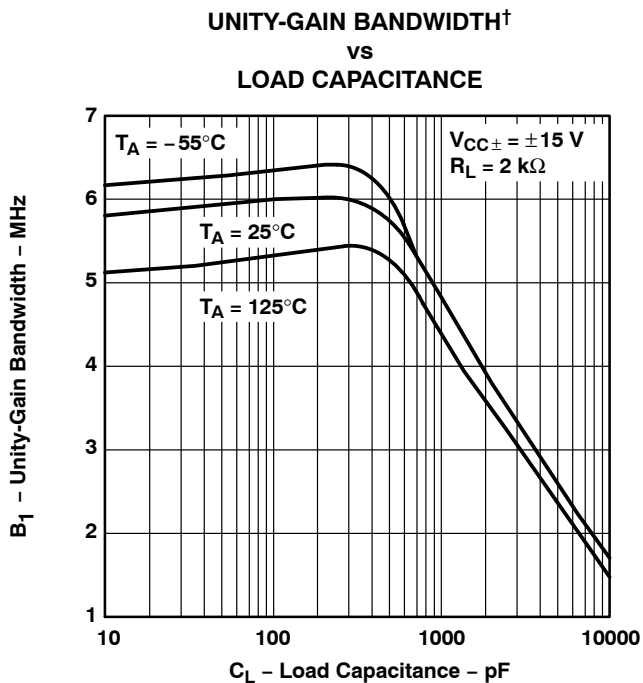
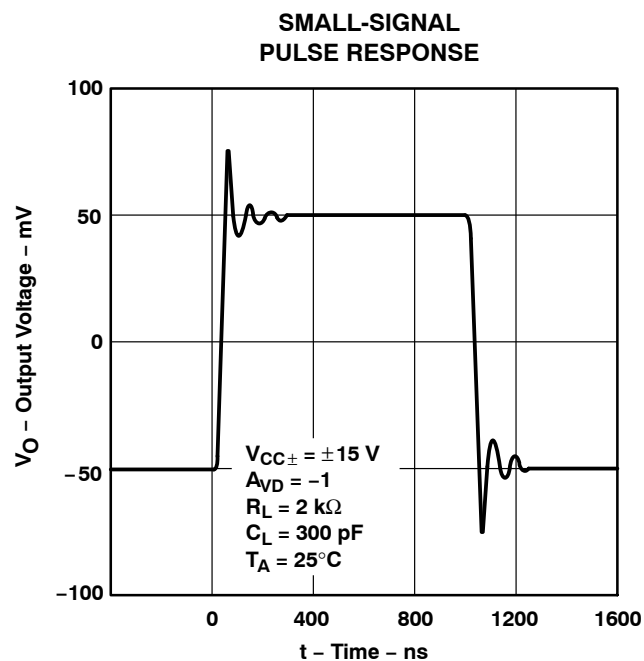
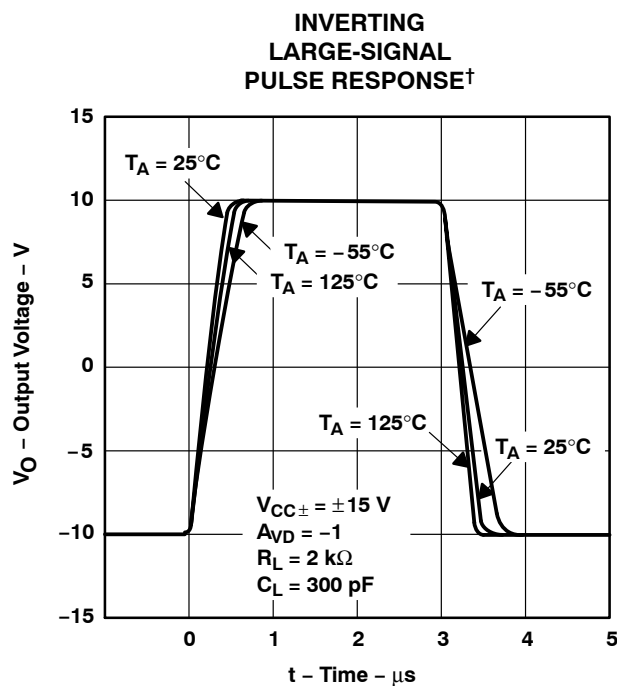
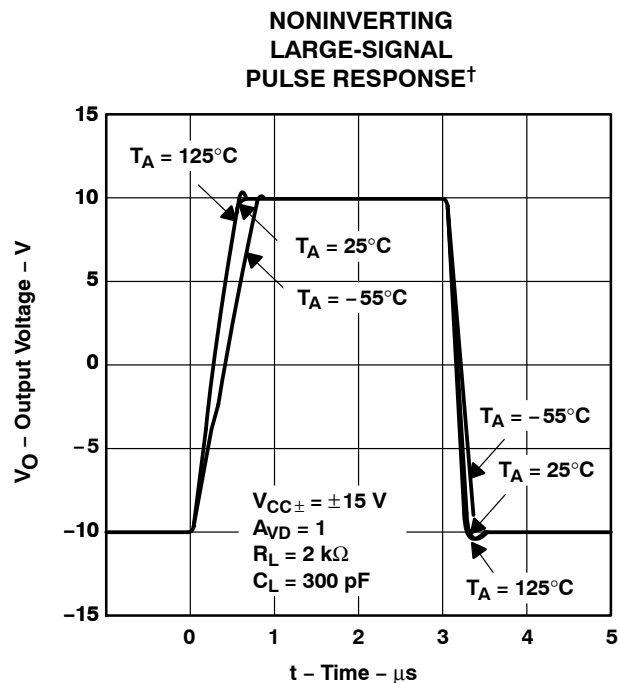
Figure 30

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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TYPICAL CHARACTERISTICS



† Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

TYPICAL CHARACTERISTICS

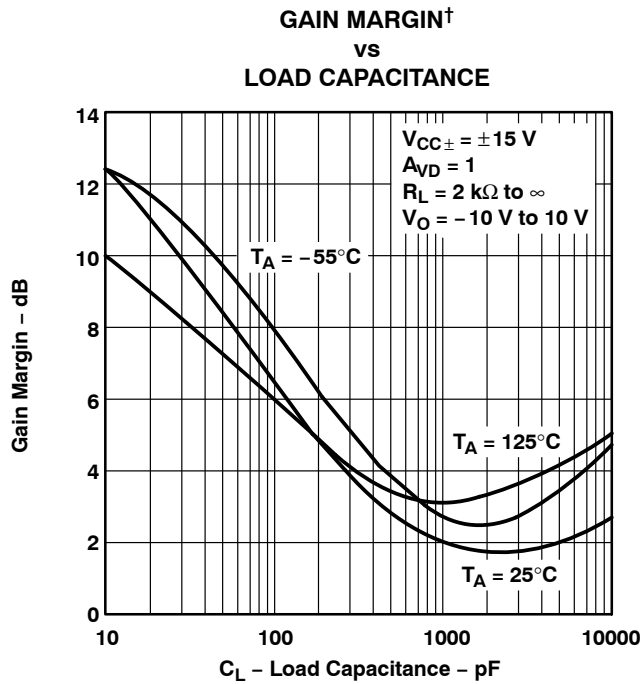


Figure 35

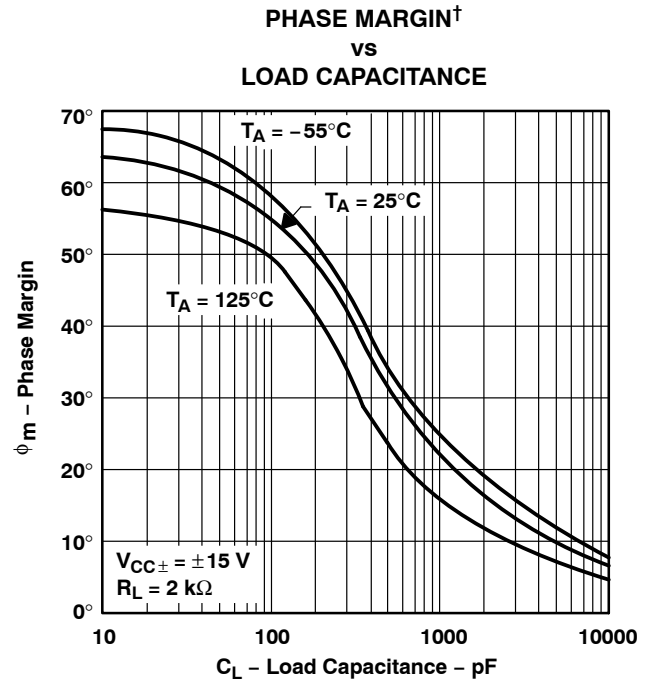


Figure 36

[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices.

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APPLICATION INFORMATION

input offset voltage nulling

The TLE2141 series offers external null pins that can be used to further reduce the input offset voltage. If this feature is desired, connect the circuit of Figure 37 as shown. If external nulling is not needed, the null pins may be left unconnected.

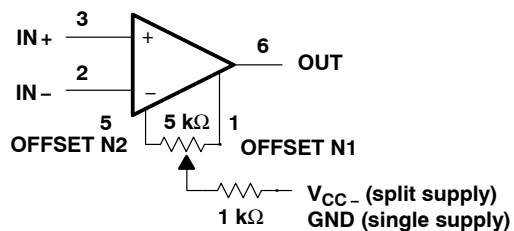


Figure 37. Input Offset Voltage Null Circuit

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
5962-9321603Q2A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	-55 to 125	5962-9321603Q2A TLE2142MFKB	Samples
5962-9321603QHA	ACTIVE	CFP	U	10	1	TBD	Call TI	Call TI	-55 to 125	9321603QHA TLE2142M	Samples
5962-9321603QPA	ACTIVE	CDIP	JG	8	1	TBD	Call TI	Call TI	-55 to 125	9321603QPA TLE2142M	Samples
5962-9321604Q2A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	-55 to 125	5962-9321604Q2A TLE2142 AMFKB	Samples
5962-9321604QHA	ACTIVE	CFP	U	10	1	TBD	Call TI	Call TI	-55 to 125	9321604QHA TLE2142AM	Samples
5962-9321604QPA	ACTIVE	CDIP	JG	8	1	TBD	Call TI	Call TI	-55 to 125	9321604QPA TLE2142AM	Samples
5962-9321605Q2A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	-55 to 125	5962-9321605Q2A TLE2144MFKB	Samples
5962-9321605QCA	ACTIVE	CDIP	J	14	1	TBD	Call TI	Call TI	-55 to 125	5962-9321605QC A TLE2144MJB	Samples
5962-9321606Q2A	ACTIVE	LCCC	FK	20	1	TBD	Call TI	Call TI	-55 to 125	5962-9321606Q2A TLE2144 AMFKB	Samples
5962-9321606QCA	ACTIVE	CDIP	J	14	1	TBD	Call TI	Call TI	-55 to 125	5962-9321606QC A TLE2144AMJB	Samples
TLE2141ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141AC	Samples
TLE2141ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141AC	Samples
TLE2141ACP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2141AC	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLE2141ACPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2141AC	Samples
TLE2141AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141AI	Samples
TLE2141AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141AI	Samples
TLE2141AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141AI	Samples
TLE2141AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141AI	Samples
TLE2141AIP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLE2141AI	Samples
TLE2141AIPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TLE2141AI	Samples
TLE2141CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141C	Samples
TLE2141CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141C	Samples
TLE2141CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141C	Samples
TLE2141CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141C	Samples
TLE2141CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2141CP	Samples
TLE2141CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2141CP	Samples
TLE2141ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141I	Samples
TLE2141IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141I	Samples
TLE2141IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141I	Samples
TLE2141IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2141I	Samples
TLE2141IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2141IP	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLE2141IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2141IP	Samples
TLE2141MD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2141M	Samples
TLE2141MDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2141M	Samples
TLE2142ACD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142AC	Samples
TLE2142ACDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142AC	Samples
TLE2142ACDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142AC	Samples
TLE2142ACDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142AC	Samples
TLE2142ACP	OBSOLETE	PDIP	P	8		TBD	Call TI	Call TI	0 to 70		
TLE2142AID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142AI	Samples
TLE2142AIDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142AI	Samples
TLE2142AIDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142AI	Samples
TLE2142AIDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142AI	Samples
TLE2142AIP	OBSOLETE	PDIP	P	8		TBD	Call TI	Call TI			
TLE2142AMD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	E2142A	Samples
TLE2142AMDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		E2142A	Samples
TLE2142AMDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	E2142A	Samples
TLE2142AMDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		E2142A	Samples
TLE2142AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9321604Q2A TLE2142 AMFKB	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLE2142AMJG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type		TLE2142AMJG	Samples
TLE2142AMJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9321604QPA TLE2142AM	Samples
TLE2142AMUB	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9321604QHA TLE2142AM	Samples
TLE2142CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142C	Samples
TLE2142CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142C	Samples
TLE2142CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142C	Samples
TLE2142CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142C	Samples
TLE2142CP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2142CP	Samples
TLE2142CPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2142CP	Samples
TLE2142CPWLE	OBSOLETE	TSSOP	PW	16		TBD	Call TI	Call TI			
TLE2142CPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		Q2142	Samples
TLE2142CPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		Q2142	Samples
TLE2142ID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142I	Samples
TLE2142IDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142I	Samples
TLE2142IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142I	Samples
TLE2142IDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142I	Samples
TLE2142IP	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2142IP	Samples
TLE2142IPE4	ACTIVE	PDIP	P	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2142IP	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLE2142MD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2142M	Samples
TLE2142MDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142M	Samples
TLE2142MDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	2142M	Samples
TLE2142MDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		2142M	Samples
TLE2142MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9321603Q2A TLE2142MFKB	Samples
TLE2142MJGB	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	9321603QPA TLE2142M	Samples
TLE2142MUB	ACTIVE	CFP	U	10	1	TBD	A42	N / A for Pkg Type	-55 to 125	9321603QHA TLE2142M	Samples
TLE2144ACN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2144ACN	Samples
TLE2144ACNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2144ACN	Samples
TLE2144AIN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2144AIN	Samples
TLE2144AINE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2144AIN	Samples
TLE2144AMFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9321606Q2A TLE2144 AMFKB	Samples
TLE2144AMJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9321606QC A TLE2144AMJB	Samples
TLE2144CDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144C	Samples
TLE2144CDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144C	Samples
TLE2144CDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144C	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TLE2144CDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144C	Samples
TLE2144CN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2144CN	Samples
TLE2144CNE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2144CN	Samples
TLE2144IDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144I	Samples
TLE2144IDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144I	Samples
TLE2144IDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144I	Samples
TLE2144IDWRG4	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144I	Samples
TLE2144IN	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2144IN	Samples
TLE2144INE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type		TLE2144IN	Samples
TLE2144MDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	TLE2144M	Samples
TLE2144MDWG4	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM		TLE2144M	Samples
TLE2144MFKB	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9321605Q2A TLE2144MFKB	Samples
TLE2144MJB	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9321605QC A TLE2144MJB	Samples
TLE2144MN	OBSOLETE	PDIP	N	14		TBD	Call TI	Call TI	-55 to 125		

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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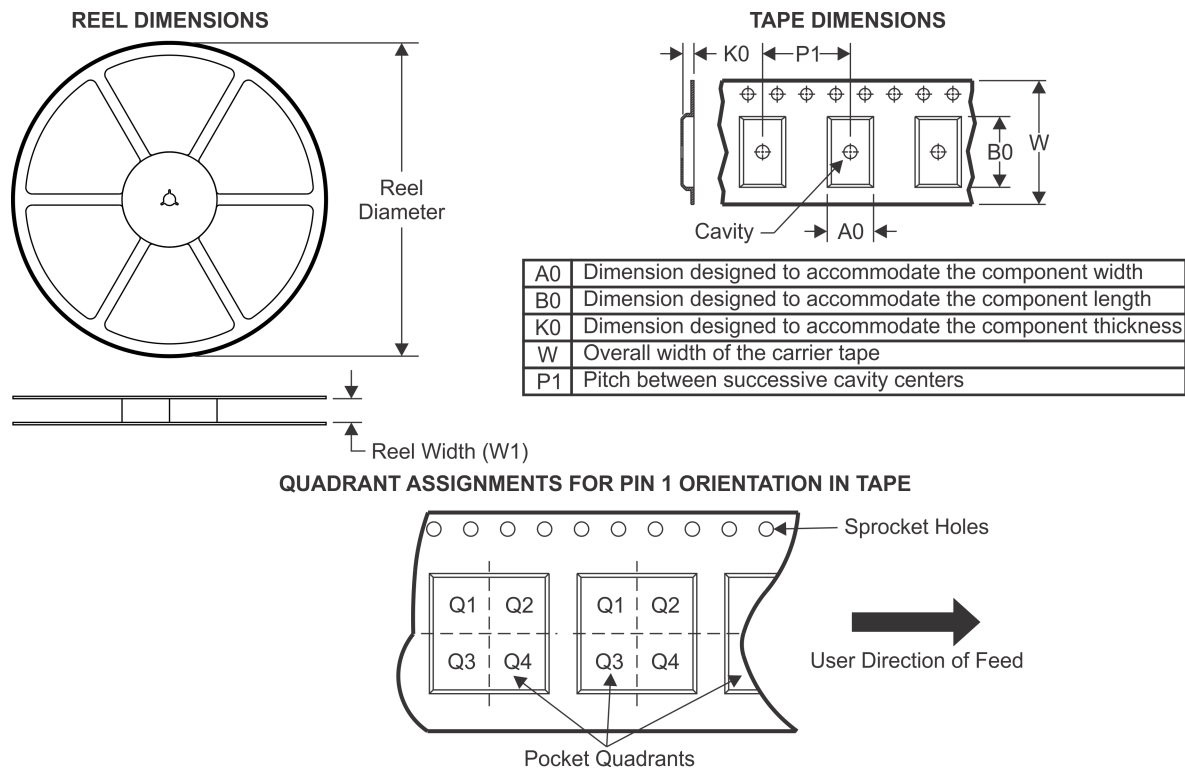
OTHER QUALIFIED VERSIONS OF TLE2141, TLE2141A, TLE2142, TLE2142A, TLE2142AM, TLE2142M, TLE2144, TLE2144A, TLE2144AM, TLE2144M :

- Catalog: [TLE2142A](#), [TLE2142](#), [TLE2144A](#), [TLE2144](#)
- Automotive: [TLE2141-Q1](#), [TLE2142-Q1](#), [TLE2142-Q1](#)
- Enhanced Product: [TLE2141-EP](#), [TLE2144-EP](#), [TLE2144-EP](#)
- Military: [TLE2141M](#), [TLE2141AM](#), [TLE2142M](#), [TLE2142AM](#), [TLE2144M](#), [TLE2144AM](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

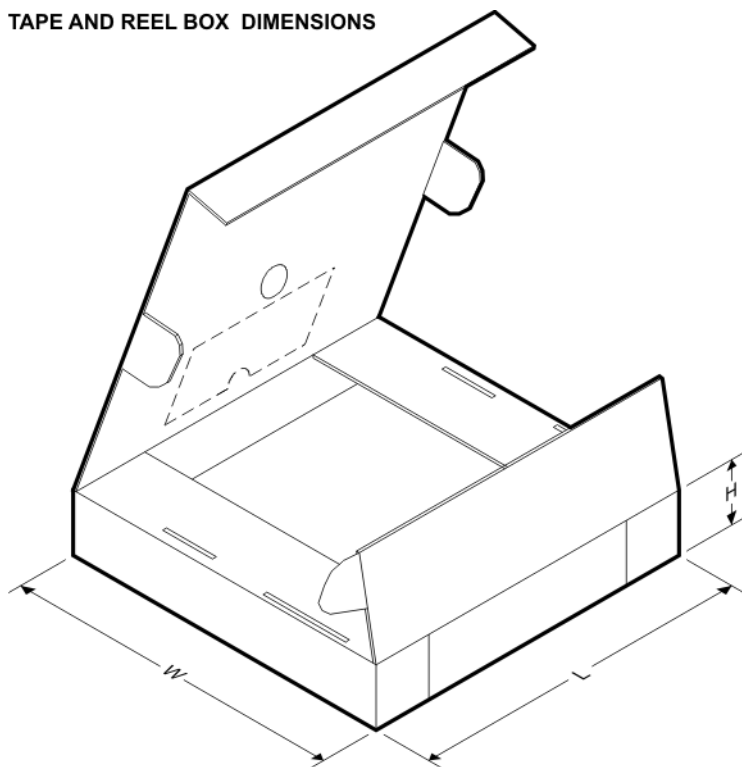
-
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2141AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2141CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2141IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2141MDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142AMDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142AMDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142CPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLE2142IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142MDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2142MDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLE2144CDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TLE2144IDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

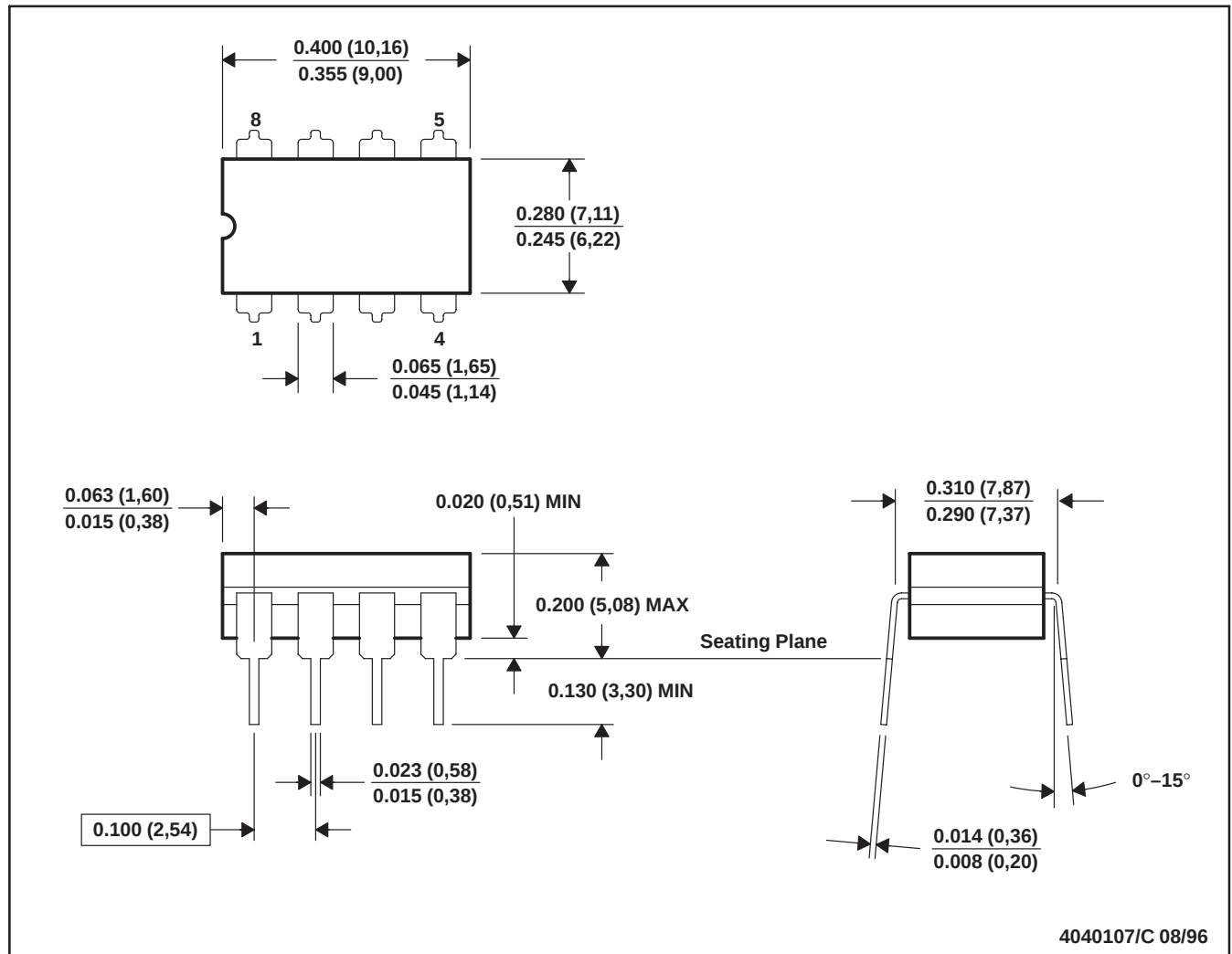


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLE2141AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2141CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2141IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2141MDR	SOIC	D	8	2500	367.0	367.0	35.0
TLE2142ACDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2142AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2142AMDR	SOIC	D	8	2500	367.0	367.0	35.0
TLE2142AMDRG4	SOIC	D	8	2500	367.0	367.0	35.0
TLE2142CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2142CPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
TLE2142IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLE2142MDR	SOIC	D	8	2500	367.0	367.0	35.0
TLE2142MDRG4	SOIC	D	8	2500	367.0	367.0	35.0
TLE2144CDWR	SOIC	DW	16	2000	367.0	367.0	38.0
TLE2144IDWR	SOIC	DW	16	2000	367.0	367.0	38.0

JG (R-GDIP-T8)

CERAMIC DUAL-IN-LINE

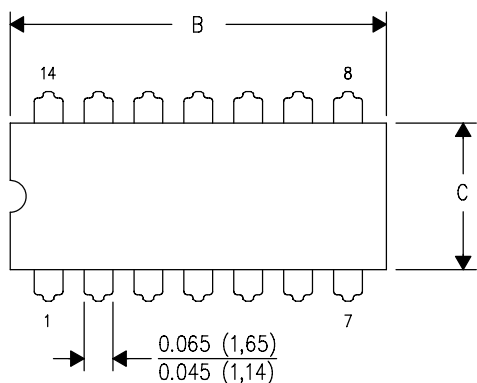


- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. This package can be hermetically sealed with a ceramic lid using glass frit.
 D. Index point is provided on cap for terminal identification.
 E. Falls within MIL STD 1835 GDIP1-T8

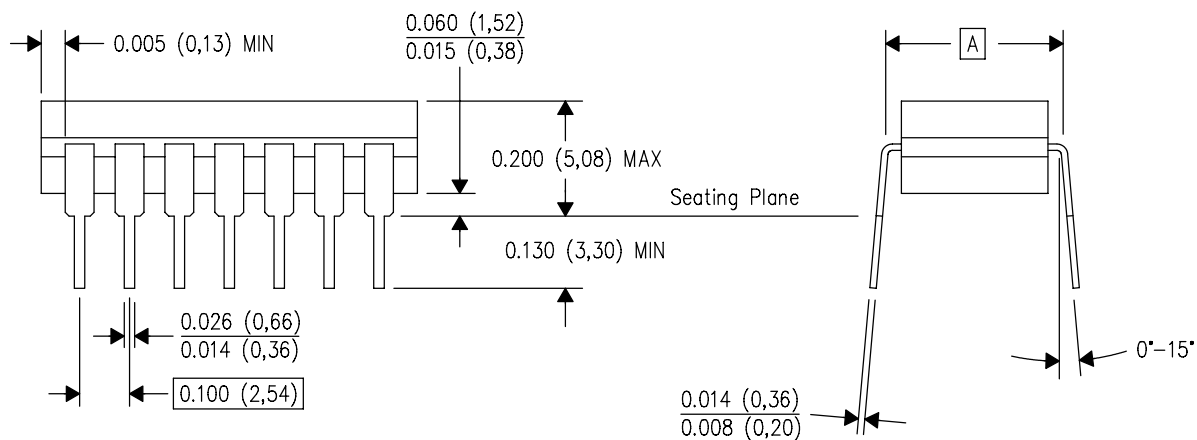
J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)

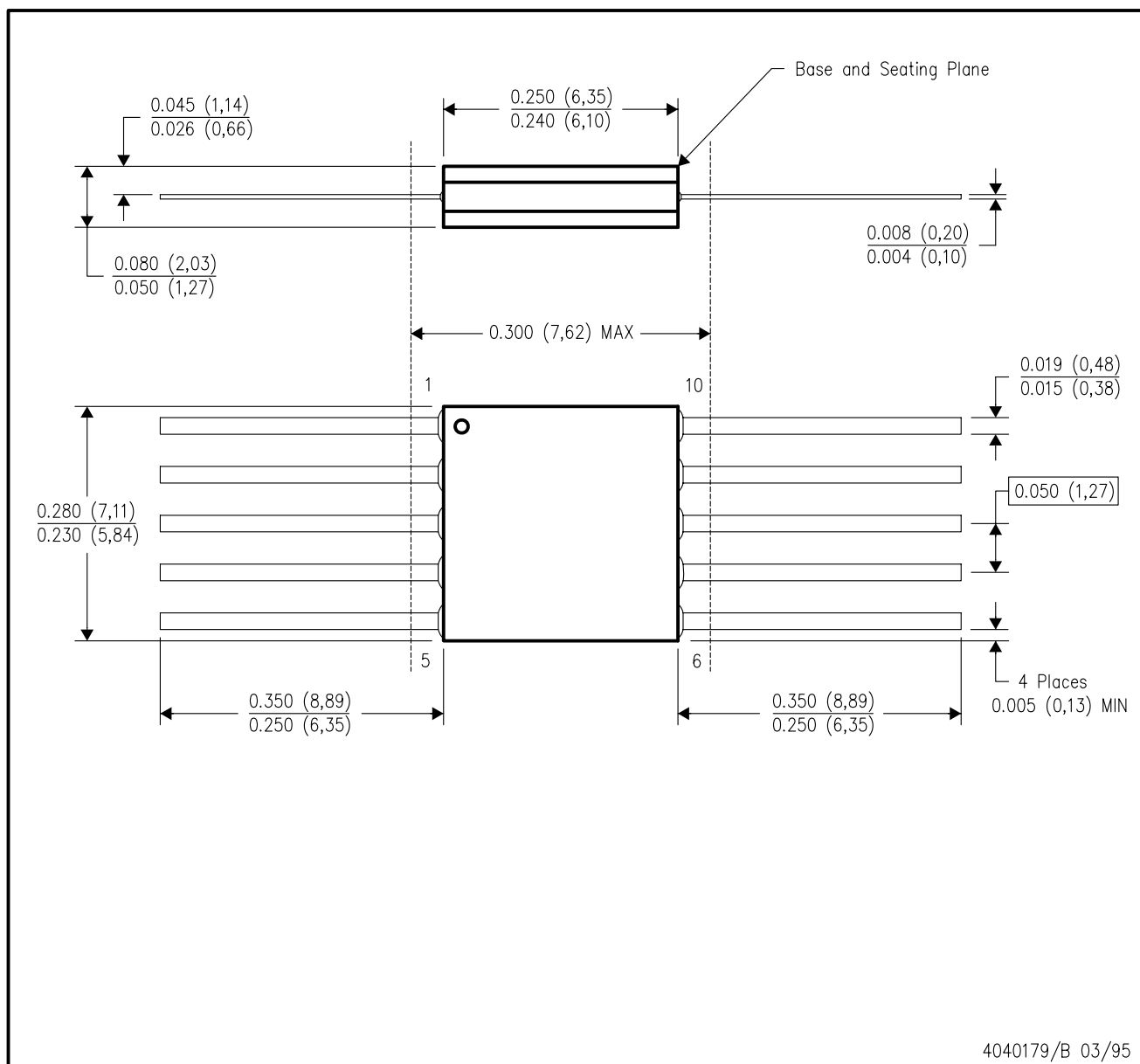


4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

U (S-GDFP-F10)

CERAMIC DUAL FLATPACK

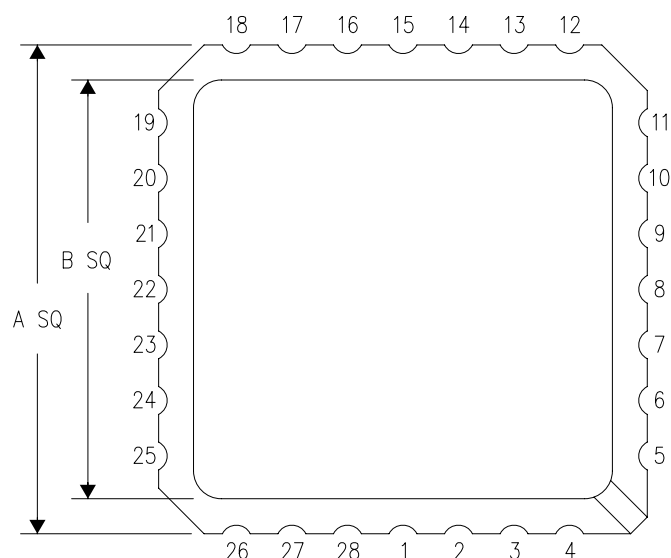


- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a ceramic lid using glass frit.
 - Index point is provided on cap for terminal identification only.
 - Falls within MIL STD 1835 GDFP1-F10 and JEDEC MO-092AA

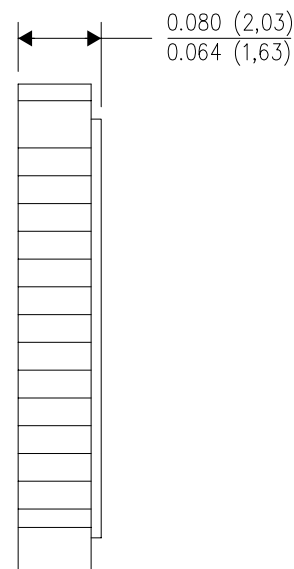
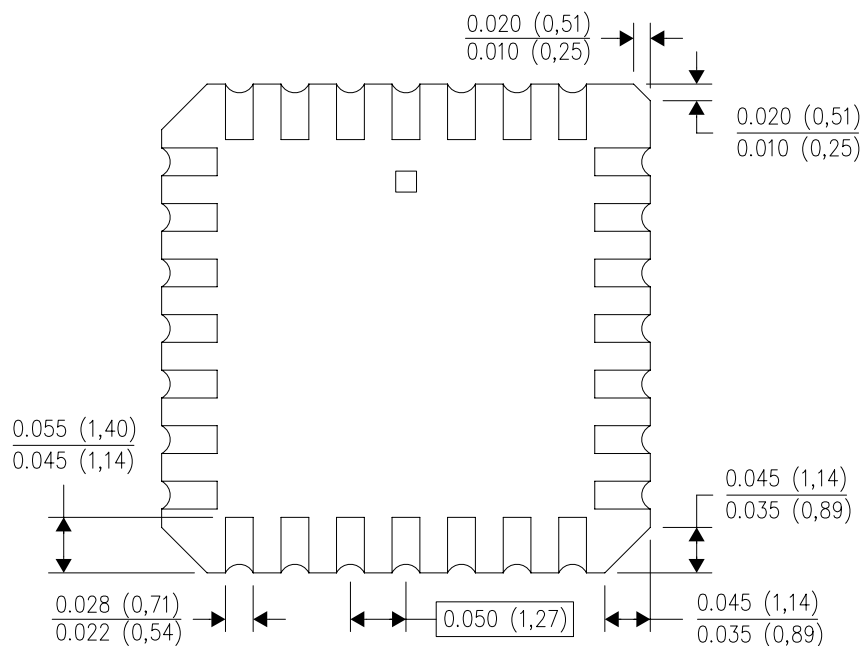
FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.740 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)



4040140/D 01/11

- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a metal lid.
 - Falls within JEDEC MS-004

P (R-PDIP-T8)

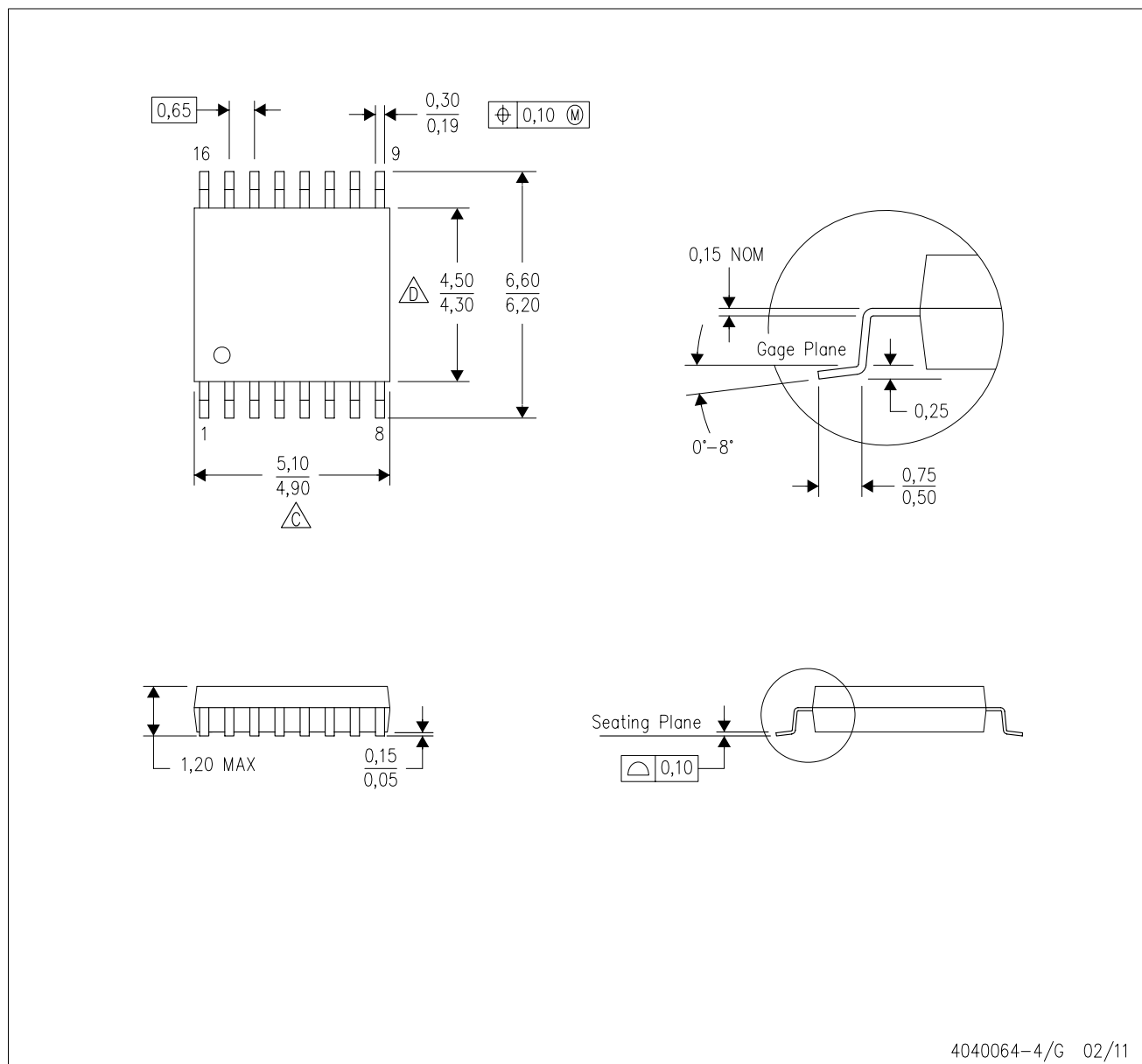
PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

PW (R-PDSO-G16)

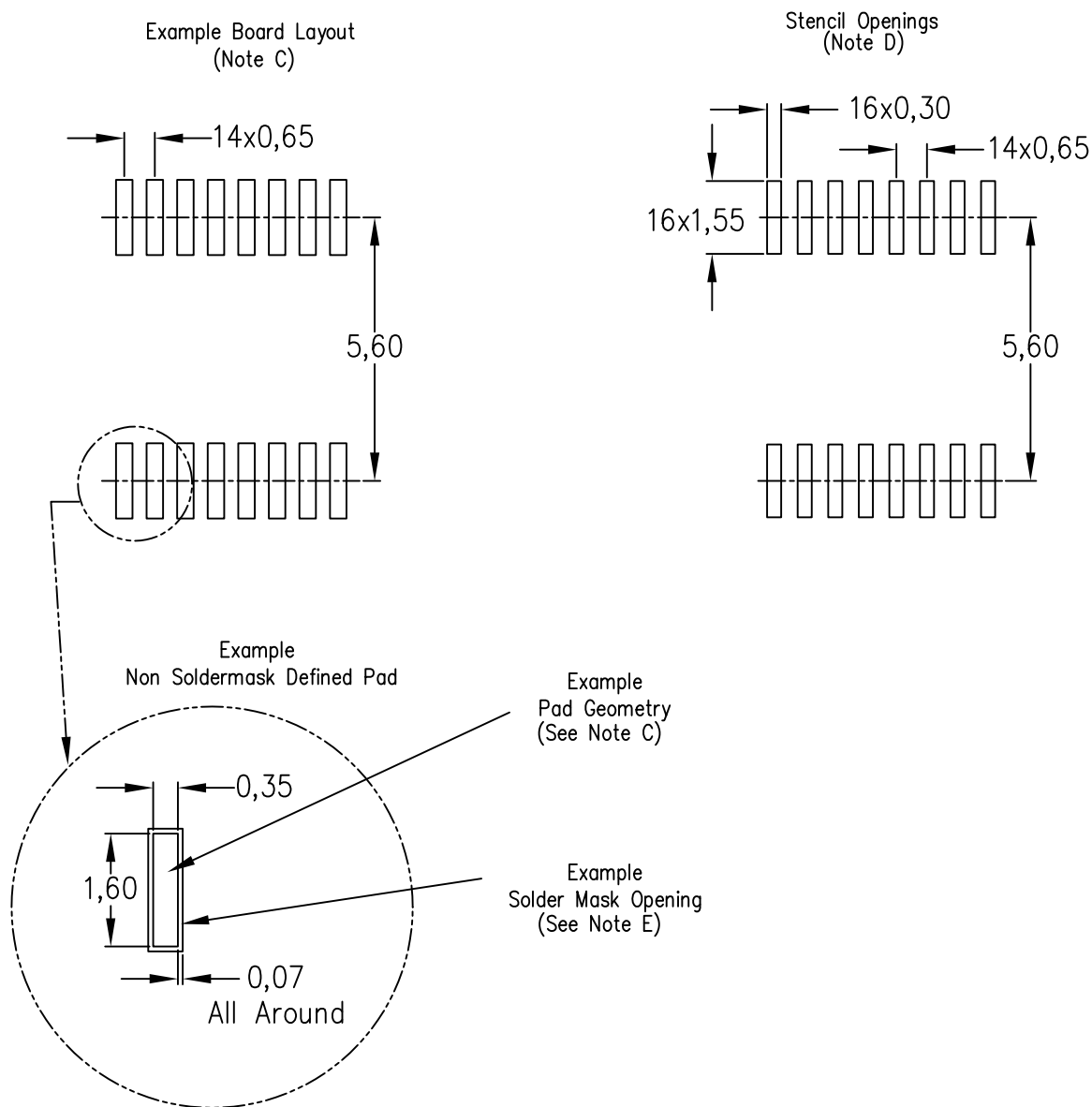
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE

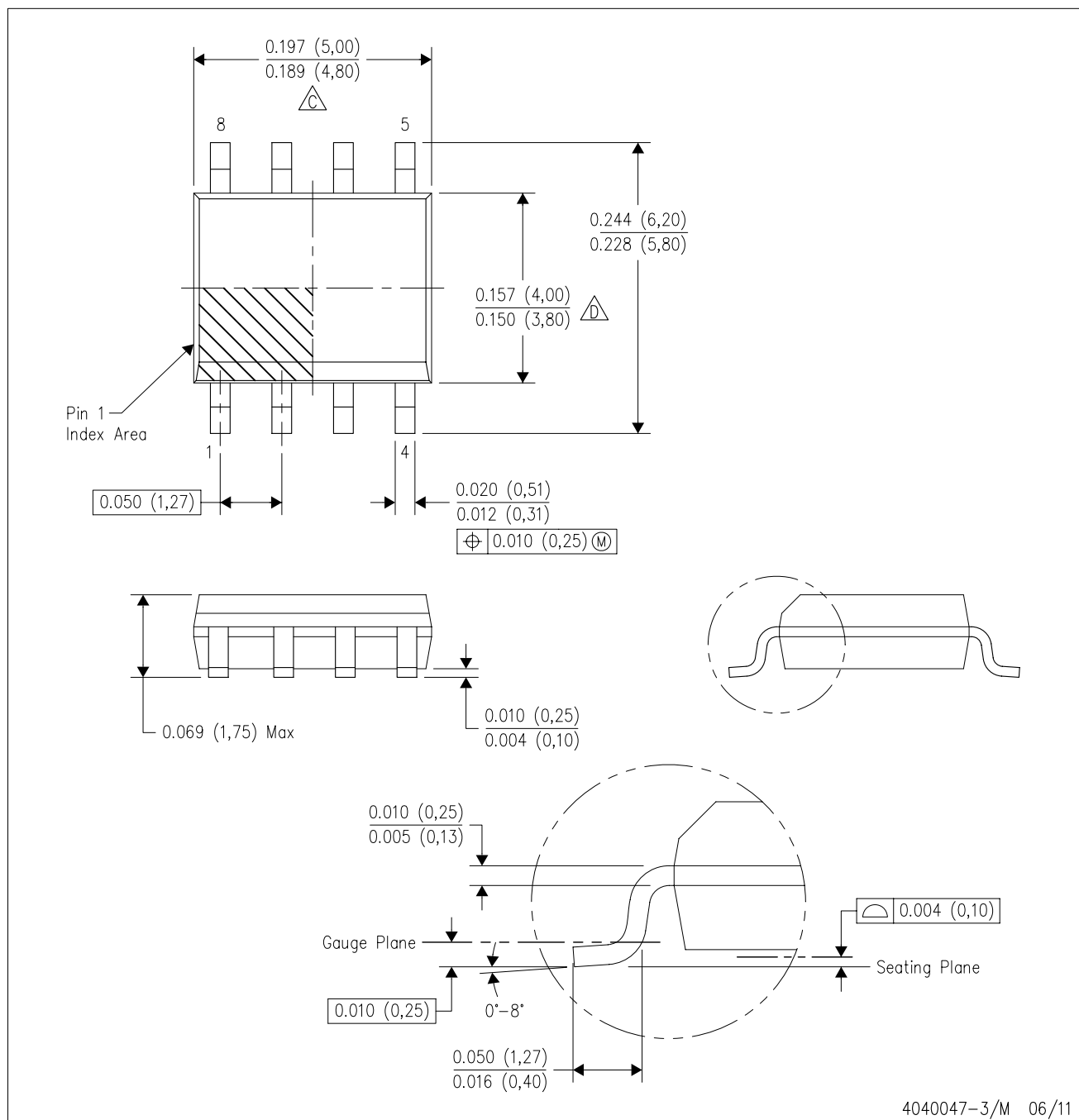


4211284-3/F 12/12

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

D (R-PDSO-G8)

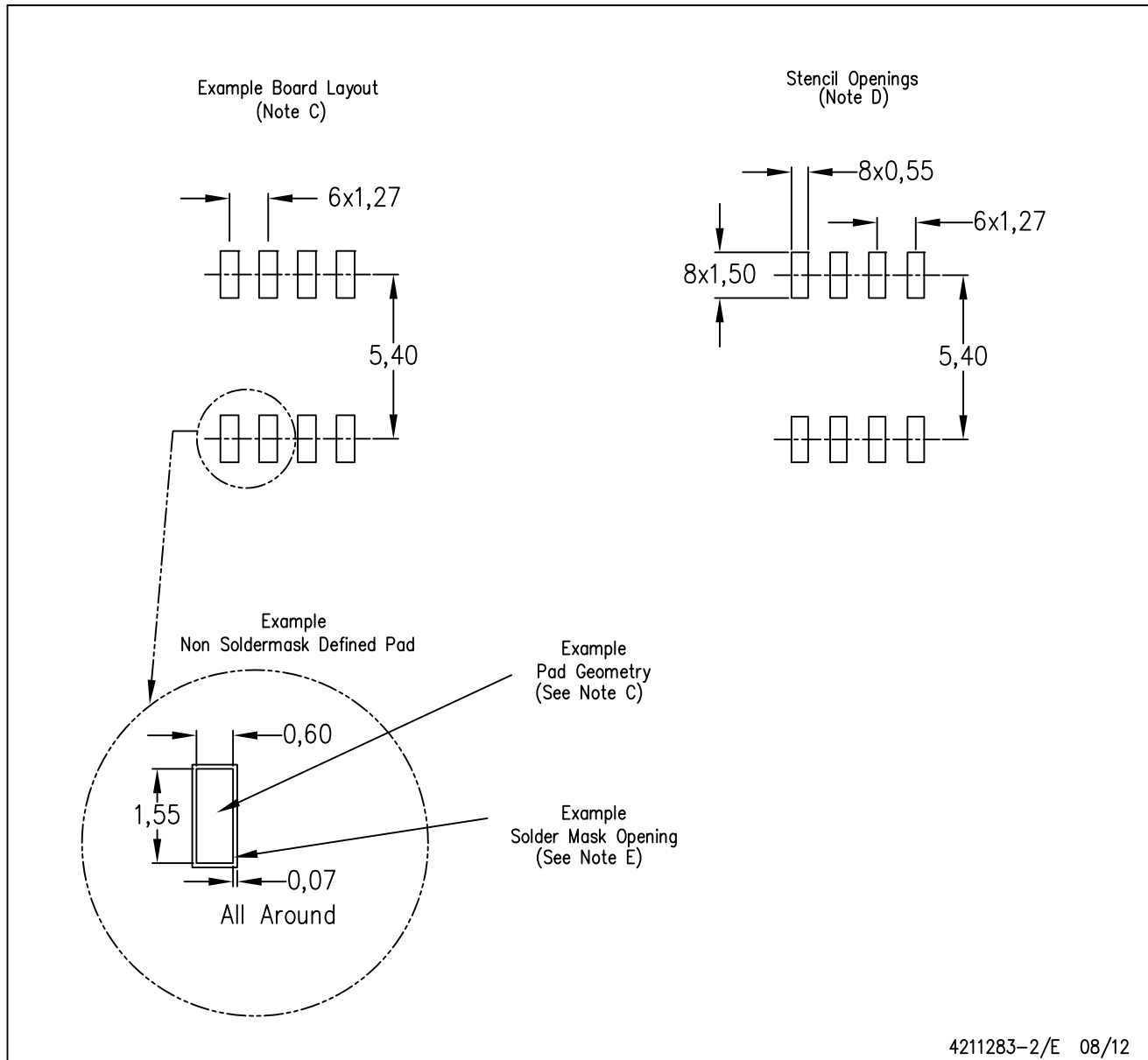
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE

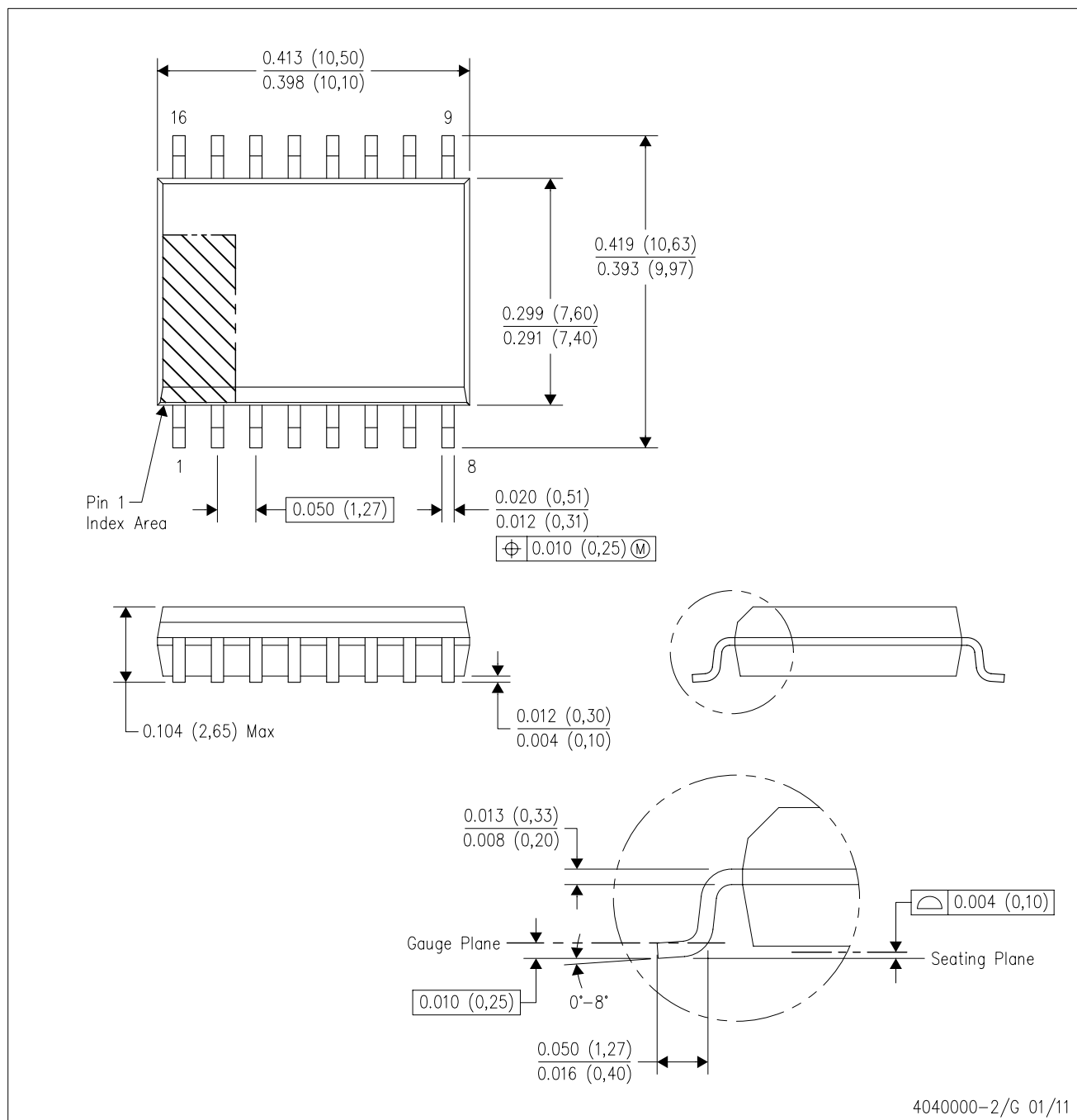


4211283-2/E 08/12

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
D. Falls within JEDEC MS-013 variation AA.

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